

Crystal Growth and Physical Properties of SrCu_2As_2 , SrCu_2Sb_2 and BaCu_2Sb_2

V. K. Anand,* P. Kanchana Perera, Abhishek Pandey, R. J. Goetsch, A. Kreyssig, and D. C. Johnston†
Ames Laboratory and Department of Physics and Astronomy, Iowa State University, Ames, Iowa 50011

(Dated: June 11, 2012)

We report the growth of single crystals of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 using the self-flux technique and their structural, magnetic, thermal and transport properties that were investigated by powder x-ray diffraction (XRD), magnetic susceptibility χ , specific heat C_p and electrical resistivity ρ measurements versus temperature T from 1.8 to 350 K. Rietveld refinements of XRD patterns for crushed crystals confirm that SrCu_2As_2 crystallizes in the ThCr_2Si_2 -type body-centered tetragonal structure (space group $I4/mmm$) and SrCu_2Sb_2 crystallizes in the CaBe_2Ge_2 -type primitive tetragonal structure (space group $P4/nmm$). However, as reported previously, BaCu_2Sb_2 is found to have a large unit cell consisting of three blocks. Here a ThCr_2Si_2 -type block is sandwiched between two CaBe_2Ge_2 -type blocks along the c -axis with an overall symmetry of $I4/mmm$, as reported, but likely with a monoclinic distortion. The χ data of all these compounds are diamagnetic and reveal nearly T -independent anisotropic behavior. The χ of SrCu_2As_2 is found to be larger in the ab -plane than along the c -axis, as also previously reported for pure and doped BaFe_2As_2 , whereas the χ values of SrCu_2Sb_2 and BaCu_2Sb_2 are larger along the c -axis. This difference in anisotropy appears to arise from the differences between the crystal structures. The finite values of the Sommerfeld linear specific heat coefficients γ and the T dependences of ρ reveal metallic character of all four compounds. The electronic and magnetic properties indicate that these compounds are sp metals with Cu in the nonmagnetic $3d^{10}$ electronic configuration corresponding to the oxidation state Cu^{+1} , as previously predicted theoretically for SrCu_2As_2 by D. J. Singh [Phys. Rev. B **79**, 153102 (2009)]. We present a brief review of theoretical and experimental work on the doping character of transition metals for Fe in BaFe_2As_2 . The As–As covalent interlayer bond distances in the collapsed-tetragonal $(\text{Ca},\text{Sr},\text{Ba})\text{Cu}_2\text{As}_2$ compounds are much shorter than the nonbonding As–As distances in BaFe_2As_2 . Thus the electronic character of the Cu and the strength of the As–As interlayer bonding are both expected to drastically change between weakly Cu-substituted BaFe_2As_2 and pure BaCu_2As_2 , perhaps via a first-order lattice instability such as a miscibility gap in the $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ system.

PACS numbers: 74.70.Xa, 72.15.Eb, 65.40.Ba, 74.70.Dd

I. INTRODUCTION

The observation of superconductivity with transition temperatures T_c up to 38 K in 122-type iron pnictides (e.g., $\text{A}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ compounds, $A = \text{Ca}, \text{Sr}, \text{Ba}, \text{and Eu}$)^{1–5} having the layered ThCr_2Si_2 -type structure, shortly after the discovery of superconductivity with T_c up to 55 K in 1111-type oxypnictides (e.g., $\text{LnFeAsO}_{1-x}\text{F}_x$ compounds, $\text{Ln} = \text{La}, \text{Ce}, \text{Nd}$ and Sm),^{6–10} triggered research activities worldwide and it is now believed that the iron pnictide compounds represent a new class of high- T_c superconductors.^{11–13} Superconductivity in these iron arsenides lies in close proximity to antiferromagnetic (AFM) itinerant spin density wave (SDW) transitions that can be easily suppressed by substitutions at the A , Fe and/or As sites.¹¹ The generic phase diagram for the emergence of superconductivity upon suppression of the SDW transition in iron arsenides is qualitatively similar to that of the high- T_c cuprates, although with the important difference that the cuprate parent compounds are local moment antiferromagnetic insulators whereas the iron arsenide parent compounds are itinerant SDW semimetals.^{11–17} Interestingly, as noted above superconductivity in iron arsenides can be induced by substitutions on the Fe site by other transition metals, which is quite different from the high-

T_c cuprate superconductors where such substitutions at the Cu site never induce superconductivity and indeed can lead to a rapid suppression of the superconductivity.

In the fiducial 122-type compound BaFe_2As_2 , the formal oxidation states of the atoms are assigned as Ba^{+2} , Fe^{+2} and As^{-3} so the Fe atoms are formally in the $3d^6$ electronic configuration as also occurs in the 1111-type parent compounds.¹¹ It has been observed that partial Co and Ni substitutions at the Fe site in BaFe_2As_2 induce superconductivity^{18–20} with T_c up to 25 K whereas no superconductivity is induced by Mn (Refs. 21–23) or Cr (Refs. 24, 25) substitutions. These findings suggest that the superconductivity might have some relation with the average number of $3d$ conduction electrons of the transition metal atom. That is, hole-doping with a smaller number of $3d$ electrons (Mn^{+2} , Cr^{+2}) than that of Fe^{+2} does not induce superconductivity, whereas electron-doping with more $3d$ electrons than Fe^{+2} (Co^{+2} and Ni^{+2}) does induce superconductivity. From this point of view divalent copper Cu^{+2} with the $3d^9$ electronic configuration and three more d -electrons than Fe should be a strong electron dopant for iron arsenide superconductors. However, Cu-doping for Fe in BaFe_2As_2 has been found to yield strongly suppressed $T_c \lesssim 2$ K in $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$, and then only in a very limited concentration range near $x = 0.044$, even

though the Cu doping suppresses the structural/SDW transition of the parent compound BaFe_2As_2 .²⁶ Simultaneous Co- and Cu-doping for Fe in BaFe_2As_2 leads to superconductivity with higher values of T_c for $y > 0$ in $\text{Ba}(\text{Fe}_{1-x-y}\text{Co}_y\text{Cu}_x)_2\text{As}_2$ compounds than for $y = 0$ (Ref. 26). On the other hand, the application of pressure to AFe_2As_2 ($\text{A} = \text{Sr}$ or Ba) compounds or isoelectronic substitutions of Ru for Fe or P for As in BaFe_2As_2 , which nominally do not result in charge doping, can also induce high- T_c superconductivity.¹¹

A +2 oxidation state of copper also plays a key role in high- T_c cuprates such as in the antiferromagnetic insulator parent compound La_2CuO_4 with a Néel temperature of 325 K where the Cu^{+2} $3d^9$ ion carries a local magnetic moment with spin $S = 1/2$ due to the single hole in the Cu $3d$ -shell.^{14–17} Then hole doping such as in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ leads to high- T_c superconductivity where the localized Cu magnetic moment is retained and the antiferromagnetic correlations between them are likely involved with the superconducting mechanism.¹⁴ Considering this feature, we speculated that a 122-type compound containing Cu^{+2} local moments with $S = 1/2$ completely replacing the Fe in the Fe-sites of the 122-type compounds might bridge the gap between the two families of high- T_c superconductors and enrich our knowledge of the physics of high- T_c superconductivity in general. This would complement our recent discovery that $\text{Ba}_{1-x}\text{K}_x\text{Mn}_2\text{As}_2$ is such an antiferromagnetic local-moment metal where the Mn^{+2} ions have a large spin $S = 5/2$.^{27,28}

Electronic structure calculations for SrCu_2As_2 and BaCu_2As_2 by D. J. Singh predicted that the Cu $3d$ bands are narrow and are located about 3 eV below the Fermi energy E_F .²⁹ These calculations also found that there is little contribution to the density of states at E_F from the Cu $3d$ orbitals. Therefore these compounds are predicted to be *sp*-band metals with the Cu atoms having a formal oxidation state of Cu^{+1} and a nonmagnetic and chemically inert $3d^{10}$ electronic configuration.²⁹

To investigate these issues, we synthesized single crystals of the previously known^{30–33} Cu-based compounds SrCu_2As_2 , SrCu_2Sb_2 and BaCu_2Sb_2 and measured their structural, magnetic, thermal and electronic transport properties, and report here our results. We also synthesized and studied crystals of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$. To our knowledge, detailed investigations of the physical properties of these compounds have not been previously carried out. Pfisterer and Nagorsen reported in 1983 that the χ of a polycrystalline sample of SrCu_2As_2 was diamagnetic and nearly independent of T from 80 to 400 K.³³

Our measurements confirm the above theoretical prediction²⁹ that SrCu_2As_2 is an *sp*-band metal and we find that it also applies to the other three compounds studied here as well. Thus the Cu ions have a formal oxidation state of Cu^{+1} with a nonmagnetic $3d^{10}$ electronic configuration. Therefore these compounds cannot be considered to be a bridge to the high- T_c cuprates.

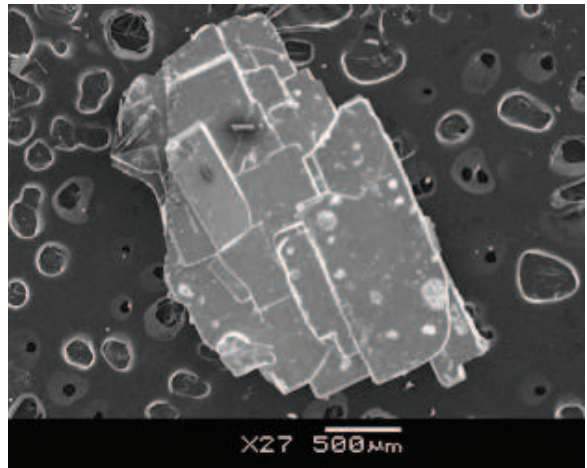


FIG. 1: (Color online) Scanning electron micrograph of a cluster of intergrown $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ crystals.

A matter of great current interest is the nature, extent and even existence of current carrier doping on substituting various transition metals for Fe in the high- T_c parent compounds $(\text{Ca}, \text{Sr}, \text{Ba})\text{Fe}_2\text{As}_2$ because of their relevance to understanding the changes in the magnetic and superconducting transition temperatures with concentration of the substituting elements. We will give a brief overview of this topic and then discuss how our results on SrCu_2As_2 relate to the previous results. We suggest that the electronic character of the Cu and the strength of the As–As interlayer bonds both strongly change between weakly Cu-substituted BaFe_2As_2 and pure BaCu_2As_2 , perhaps via a first-order lattice instability such as a miscibility gap in the $\text{Ba}(\text{Fe}_{2-x}\text{Cu}_x)_2\text{As}_2$ system.

The remainder of this paper is organized as follows. The experimental details are described in Sec. II. Section III describes the crystallographic studies. The physical properties of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 are described in Secs. IV, V, VI and VII, respectively. A discussion of our results in the context of previous work is given in Sec. VIII. In Sec. VIII A we discuss the occurrence or not of X – X interlayer covalent bonding in $(\text{Ca}, \text{Sr}, \text{Ba})M_2X_2$ compounds with the ThCr_2Si_2 structure, where $M = \text{Cr}, \text{Mn}, \text{Fe}, \text{Co}, \text{Ni}$ and Cu and $X = \text{As}$ or P , and conclude that SrCu_2As_2 is in the collapsed tetragonal phase with short As–As interlayer bonds. In Sec. VIII B we discuss the relationships between the X – X bonding and the magnetic properties. A brief review of the doping properties that occur upon substituting other transition metals for Fe in BaFe_2As_2 is given in Sec. VIII C, together with a discussion of how our results on SrCu_2As_2 impact this discussion. A summary and our conclusions are given in Sec. IX.

TABLE I: The average chemical compositions (atomic %) obtained from EDX analyses of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 crystals. The systematic error in the EDX measurements is estimated to be ~ 2 –3 atomic %.

Compound	Sr or Ba	Cu	As	Sb
SrCu_2As_2	18.3	41.5	40.2	
SrCu_2Sb_2	19.4	38.9		41.8
$\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$	18.8	40.9	34.0	6.3
BaCu_2Sb_2	19.5	39.4		41.1

II. EXPERIMENTAL DETAILS

Single crystals of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 were grown by the self-flux growth technique using the high purity elements Sr (99.95%) and Ba (99.99%) from Sigma Aldrich, and Cu (99.999%), As (99.99999%) and Sb (99.999%) from Alfa Aesar. Prereacted CuAs or CuSb were used as flux. For the growth of SrCu_2As_2 and SrCu_2Sb_2 crystals, the Sr and flux (CuAs or CuSb) were taken in a 1:5 molar ratio, placed in alumina crucibles and sealed inside evacuated quartz tubes. The crystal growth was carried out by heating the samples to 1100 °C at a rate of 60 °C/h, holding there for 12 h and then cooling to 800 °C at a rate of 2.5 °C/h. The crystals were separated from the flux by decanting the flux with a centrifuge at 800 °C, yielding shiny plate-like crystals. While the sizes of the SrCu_2Sb_2 crystals were typically $3 \times 2.5 \times 0.3 \text{ mm}^3$, one of the SrCu_2As_2 crystals was larger ($6 \times 3 \times 1 \text{ mm}^3$). In our attempt to grow crystals of the mixed compound SrCu_2AsSb starting with Sr:CuAs:CuSb in a 1:2.5:2.5 molar ratio with the same heating profile as above, we instead obtained $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ crystals as determined from energy-dispersive x-ray (EDX) analysis. In this case scanning electron microscope (SEM) images revealed intergrowths of shiny plate-like crystals stacked on top of each other (Fig. 1). The physical properties of this composition were measured on such an assembly of stacked crystals.

For the growth of BaCu_2Sb_2 crystals, Ba and CuSb were taken in a 1:5 molar ratio and heated to 1000 °C at a rate of 80 °C/h, held there for 15 h, cooled to 700 °C at a rate of 2.5 °C/h, and then the flux was decanted at 700 °C to obtain crystals of typical size $2.5 \times 2 \times 0.5 \text{ mm}^3$. We did not succeed in synthesizing single crystals of BaCu_2As_2 using the self-flux growth or with Sn as a flux with similar heating profiles.

The chemical compositions of the crystals were determined using a JEOL SEM equipped with an EDX analyzer, which showed that these are close to the respective stoichiometric compositions SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 . The average chemical compositions obtained from the EDX analyses of the single crystals are presented in Table I. The crys-

tal structures of the samples were determined by powder x-ray diffraction (XRD) measurements that were carried out on powdered crystals using a Rigaku Geigerflex x-ray diffractometer and Cu K_α radiation.

The specific heat measurements were performed by the relaxation method in zero applied magnetic field in a Quantum Design physical properties measurement system (PPMS). The electrical resistivity was measured in the *ab*-plane of each crystal in zero applied magnetic field by the standard four-probe ac technique using the ac transport option of the PPMS. The 50 μm diameter platinum wire electrical leads were attached to the crystals using silver epoxy.

Magnetization and magnetic susceptibility measurements were performed using a Quantum Design superconducting quantum interference device magnetic properties measurement system (MPMS). The single crystals were mounted either on a small piece of plastic or on a thin quartz rod using a small amount of GE 7031 varnish. We separately measured the magnetic moment of the sample holder (quartz rod/plastic and GE varnish) and subtracted it from the measured magnetic moment to obtain the sample contribution.

III. CRYSTALLOGRAPHY

The XRD data on crushed single crystals of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 were analyzed by Rietveld refinement using the FullProf³⁴ software. The room-temperature XRD patterns along with the Rietveld fit profiles are presented in Fig. 2 for SrCu_2As_2 , SrCu_2Sb_2 and $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and in Fig. 3 for BaCu_2Sb_2 . The XRD data indicate that the crushed crystals are single-phase. The unindexed peaks marked with stars arise from small amounts of flux attached to the surfaces of the crystals. The Rietveld refinements confirmed that SrCu_2As_2 crystallizes in the ThCr_2Si_2 -type body-centered tetragonal (bct) structure (space group $I4/mmm$) and SrCu_2Sb_2 crystallizes in the CaBe_2Ge_2 -type primitive tetragonal structure (space group $P4/nmm$). As seen in Fig. 4(a), the structure of SrCu_2As_2 contains stacked square lattices of Cu atoms, as in the high T_c cuprates, but the coordination of copper by the anions is quite different in the two types of material. On the other hand, the structure of SrCu_2Sb_2 contains two distinct types of Cu square lattice with different lattice parameters that are rotated by 45° from each other and stacked in a specific sequence, as seen in Fig. 4(b).

Both the ThCr_2Si_2 -type and CaBe_2Ge_2 -type structures are ternary derivatives of the BaAl_4 structure³⁵ and consist of layers of *A* (Th, Ca), *T* (Cr, Be) and *X* (Si, Ge) atoms stacked along the crystallographic *c*-axis. While the *A* atoms form a bct sublattice in both cases, the two structures differ in the arrangement of layers of *T* and *X* atoms as can be seen from Figs. 4(a) and 4(b). In the ThCr_2Si_2 -type structure the layers of

TABLE II: Crystallographic and Rietveld refinement parameters obtained from powder XRD data for crushed crystals of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 . If no value for the lattice parameter b is listed, then $b = a$. Error bars for the last digit of a quantity are given in parentheses and literature references are given in square brackets.

	SrCu_2As_2	SrCu_2Sb_2	$\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$	BaCu_2Sb_2	BaCu_2Sb_2
Structure	ThCr ₂ Si ₂ -type tetragonal	CaBe ₂ Ge ₂ -type tetragonal	ThCr ₂ Si ₂ -type tetragonal	tetragonal	orthorhombic
Space group	$I4/mmm$	$P4/nmm$	$I4/mmm$	$I4/mmm$	$Immm$
Lattice parameters					
a (Å)	4.2725(1) 4.279(1) [31] 4.271(1) [30]	4.5162(2) 4.51(1) [32]	4.2940(1)	4.6438(5) 4.655(1) [31]	4.6224(5)
b (Å)					4.6679(5)
c (Å)	10.2000(3) 10.215(1) [31] 10.18(2) [30]	10.9008(5) 10.91(2) [32]	10.3190(4)	32.600(4) 32.709(6) [31]	32.606(4)
V_{cell} (Å ³)	186.19(1)	222.33(2)	190.26(1)	703.0(1)	703.5(1)
Refinement quality					
χ^2	9.72	9.13	12.3	4.98	4.00
R_p (%)	3.70	6.81	4.59	5.13	4.77
R_{wp} (%)	5.71	9.52	7.32	6.98	6.26

TABLE III: Atomic coordinates obtained from the Rietveld refinements of powder XRD data for powdered crystals of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 .

Atom	Wyckoff symbol	x	y	z
SrCu_2As_2 ($I4/mmm$)				
Sr	2a	0	0	0
Cu	4d	0	1/2	1/4
As	4e	0	0	0.3789(1)
SrCu_2Sb_2 ($P4/nmm$)				
Sr	2c	1/4	1/4	0.2353(5)
Cu1	2a	3/4	1/4	0
Cu2	2c	1/4	1/4	0.6330(8)
Sb1	2b	3/4	1/4	1/2
Sb2	2c	1/4	1/4	0.8707(4)
$\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$				
Sr	2a	0	0	0
Cu	4d	0	1/2	1/4
As/Sb	4e	0	0	0.3781(2)
BaCu_2Sb_2 ($I4/mmm$)				
Ba1	2a	0	0	0
Ba2	4e	0	0	0.6654(4)
Cu1	4e	0	0	0.7947(7)
Cu2	8g	0	1/2	0.0830(6)
Sb1	4d	0	1/2	1/4
Sb2	4e	0	0	0.1234(3)
Sb3	4e	0	0	0.5428(3)
BaCu_2Sb_2 ($Immm$)				
Ba1	2a	0	0	0
Ba2	4i	0	0	0.6650(3)
Cu1	4i	0	0	0.7933(6)
Cu2	4j	1/2	0	0.0808(9)
Cu3	4j	1/2	0	0.5880(8)
Sb1	4j	1/2	0	0.7484(8)
Sb2	4i	0	0	0.1230(3)
Sb3	4i	0	0	0.5426(3)

atoms are in the order Th-Si-Cr-Si-Th-Si-Cr-Si-Th along the c -axis, whereas in the CaBe_2Ge_2 -type structure the order of atomic layers is Ca-Ge-Be-Ge-Ca-Be-Ge-Be-Ca. Thus in between the consecutive Ca-planes the Ge-Be-Ge slab changes into a Be-Ge-Be slab which leads to a loss of mirror symmetry about the A -plane in the CaBe_2Ge_2 -type structure that is present in the ThCr₂Si₂-type structure. $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ is found to crystallize in the bct ThCr₂Si₂-type structure.

On the other hand the XRD data for BaCu_2Sb_2 could not be described by either a ThCr₂Si₂-type or a CaBe_2Ge_2 -type structure. Instead, as reported by Dünner et al.,³¹ the structure of BaCu_2Sb_2 is an ordered intergrowth of ThCr₂Si₂- and CaBe_2Ge_2 -types of unit cells. The unit cell of BaCu_2Sb_2 consists of three of these unit cell blocks stacked along the c -axis, as shown in Fig. 4(c), leading to a large $c = 32.6$ Å, with a ThCr₂Si₂-type block sandwiched between two CaBe_2Ge_2 -type blocks resulting in an overall symmetry of $I4/mmm$. A Rietveld refinement of the XRD data of BaCu_2Sb_2 with this structural model is shown in Fig. 3(a). The overall agreement between the experimental XRD data and the calculated pattern is reasonable. However, we observe splittings of some of the XRD peaks, as illustrated in the inset of Fig. 3(a), which suggest that the symmetry is lower than the reported one.

We attempted to refine the XRD data for BaCu_2Sb_2 with a lower orthorhombic ($Immm$) symmetry, which is a subgroup of the $I4/mmm$ space group. The Rietveld refinement profile with this structural model is shown in Fig. 3(b). In terms of the goodness of fit, this structural model proved better as deduced from the respective χ^2 values in Table II, but it could not account for the magnitudes of the splittings of the peaks, as illustrated in the inset of Fig. 3(b). Further lowering of the symmetry to monoclinic space group $C2/m$, which

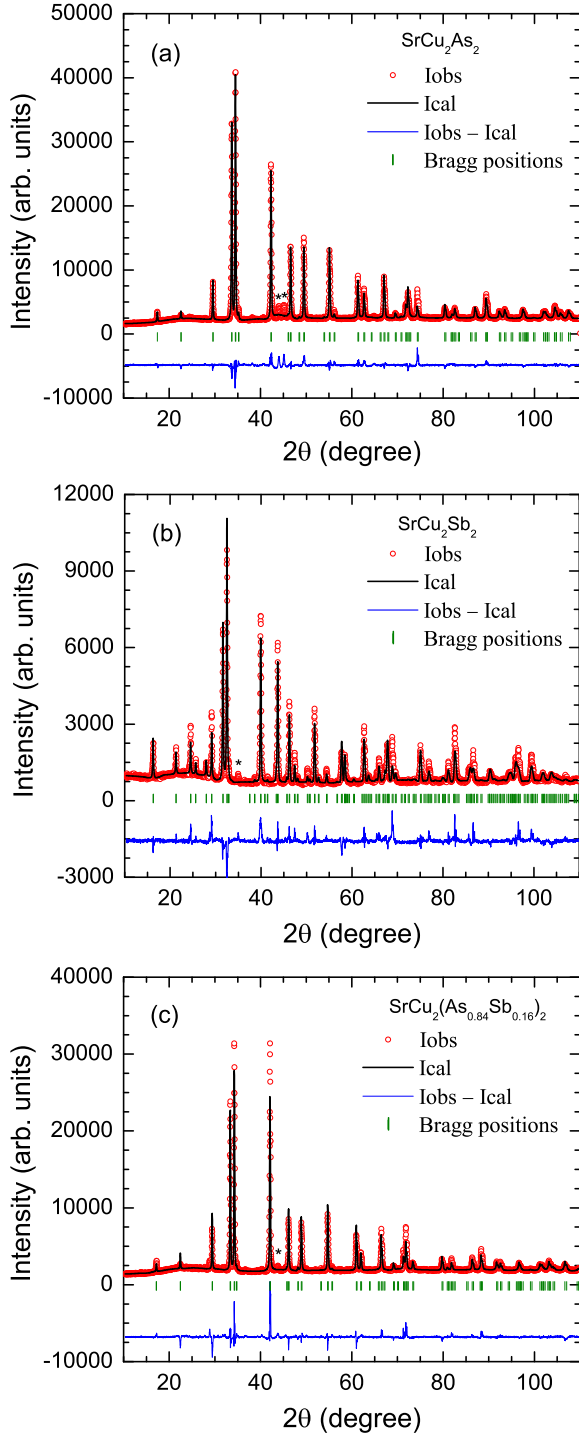


FIG. 2: (Color online) Powder x-ray diffraction patterns of (a) SrCu_2As_2 , (b) SrCu_2Sb_2 and (c) $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ recorded at room temperature. In (a) and (c), the solid lines through the experimental points are the Rietveld refinement profiles calculated for the ThCr₂Si₂-type body-centered tetragonal structure (space group $I4/mmm$), and in (b) the solid line through the data points is the Rietveld refinement profile for the CaBe₂Ge₂-type primitive tetragonal structure (space group $P4/nmm$). In (a), (b) and (c), the short vertical bars mark the fitted Bragg peak positions. The lowermost curves represent the differences between the experimental and calculated intensities. The unindexed peaks marked with stars correspond to peaks from the flux.

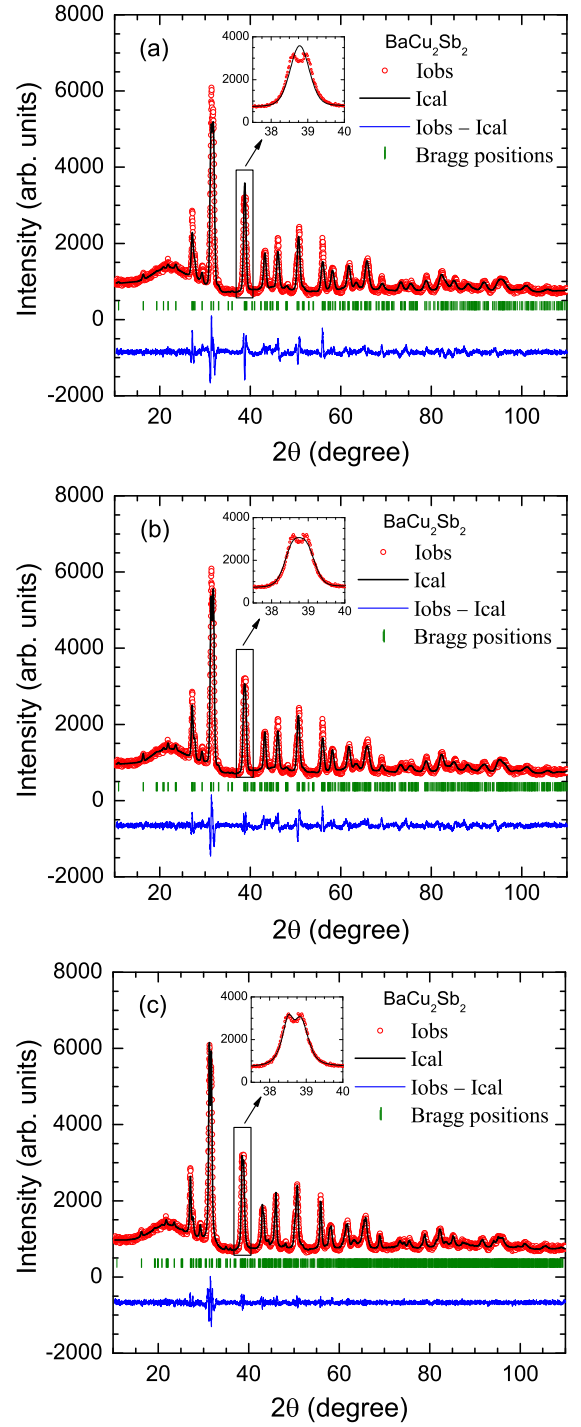


FIG. 3: (Color online) Powder x-ray diffraction pattern of BaCu_2Sb_2 recorded at room temperature. (a) The solid line through the experimental points is the Rietveld refinement profile calculated for the tetragonal structure (space group $I4/mmm$). (b) Rietveld refinement profile calculated for an orthorhombic structure (space group $Immm$). (c) Le Bail profile fit for a monoclinic structure (space group $P2_1/c$). In (a), (b) and (c), the short vertical bars mark the fitted Bragg peak positions, the lowermost curves represent the differences between the experimental and calculated intensities, and the insets show a small section of the XRD pattern highlighting an exemplary splitting and fitting of one of the peaks.

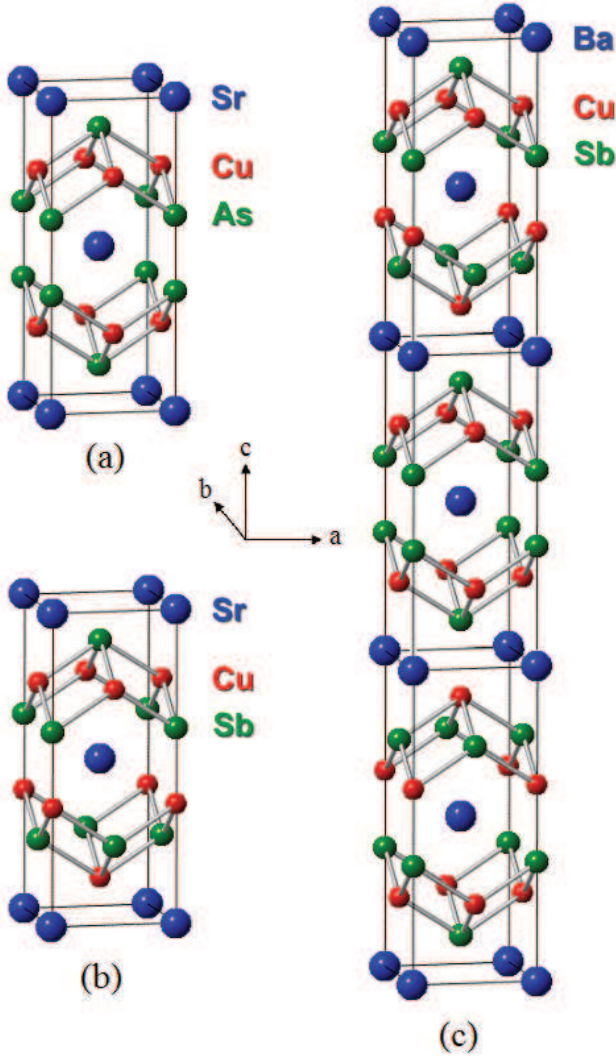


FIG. 4: (Color online) (a) ThCr_2Si_2 -type body-centered tetragonal crystal structure ($I4/mmm$) of SrCu_2As_2 . (b) CaBe_2Ge_2 -type primitive tetragonal crystal structure ($P4/nmm$) of SrCu_2Sb_2 . The order of the Cu and Sb layers in the lower half of the unit cell is reversed in (b) compared with (a). In order to compare the structures, the origin of the SrCu_2Sb_2 unit cell is shifted by $(1/4, 1/4, 1/4)$ from that for the $P4/nmm$ space group. (c) Body-centered tetragonal representation of BaCu_2Sb_2 (space group $I4/mmm$), consisting of a central ThCr_2Si_2 -type block sandwiched between two CaBe_2Ge_2 -type blocks, resulting in a large c -axis parameter $c = 32.586 \text{ \AA}$ (see Table II).

is a subgroup of $Immm$, gave a better refinement quality but could not account for all of the peaks present. Further lowering of the symmetry to space group $P2_1/c$, which is a subgroup of $C2/m$, allowed us to fit all the peak positions as illustrated in the inset of Fig. 3(c). A Le Bail profile fit for this $P2_1/c$ monoclinic structure with $a = 4.6414(3)$, $b = 4.6418(3)$, $c = 32.680(2) \text{ \AA}$ and $\beta = 90.616^\circ$ is shown in Fig. 3(c). A similar lowering of symmetry to $P2_1/c$ was necessary for the 122-type compound SrRh_2As_2 which exhibits polymorphism from

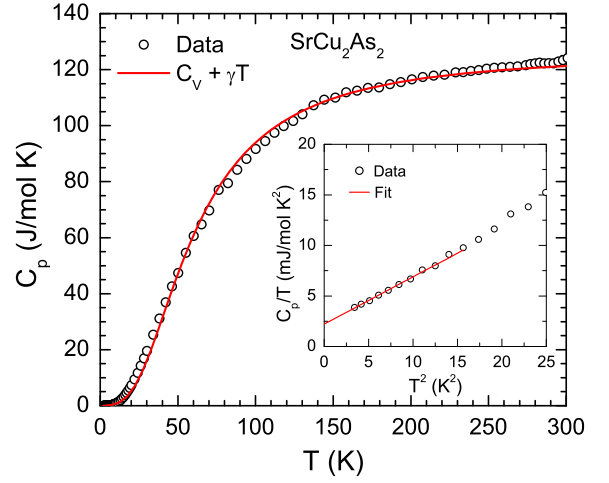


FIG. 5: (Color online) Heat capacity C_p of a SrCu_2As_2 single crystal versus temperature T . The solid red curve is a fit of the data by the sum of the contributions from the Debye lattice heat capacity $C_{V \text{ Debye}}(T)$ and predetermined electronic heat capacity γT according to Eq. (12). Inset: C_p/T vs. T^2 below 5 K. The straight line is a fit of the data for $1.85 \text{ K} \leq T \leq 3.5 \text{ K}$ by Eq. (1).

the high- T tetragonal ThCr_2Si_2 -type structure to a low- T $P2_1/c$ monoclinic structure below 350°C .³⁶ We conclude that the most likely space group is the monoclinic $P2_1/c$ that we have identified. The detailed crystal structure (determination of the precise atomic positions) remains to be determined. Our attempt to solve the structure using single crystal x-ray diffraction failed because the crystal quality was insufficient to obtain reliable data.

The crystallographic and refinement parameters of all four compounds are listed in Tables II and III. The lattice parameters obtained from our refinements are in reasonable agreement with available literature values,^{30–32} which are also listed in Table II. During the refinements the thermal parameters B were kept fixed to $B \equiv 0$ since the lattice parameters and z parameters were insensitive to change in B within the error bars. Furthermore, the occupancies of atomic positions were kept fixed at the value of unity as there were no improvements in the qualities of fit on varying the occupancies by small amounts from unity. The z coordinate of the As atoms in SrCu_2As_2 , $z_{\text{As}} = 0.3789(1)$, is very close to the reported values $z_{\text{As}} = 0.3785(1)$ (Ref. 31) and $z_{\text{As}} = 0.377$.³³ The z -coordinates $z_{\text{Sr}} = 0.2353(5)$, $z_{\text{Cu}2} = 0.6330(8)$ and $z_{\text{Sb}2} = 0.8708(4)$ of SrCu_2Sb_2 are also very close to the reported values $z_{\text{Sr}} = 0.2369(6)$, $z_{\text{Cu}2} = 0.6380(6)$ and $z_{\text{Sb}2} = 0.8695(6)$.³²

IV. PHYSICAL PROPERTIES OF SrCu_2As_2 CRYSTALS

A. Heat Capacity

The heat capacity C_p of SrCu_2As_2 as a function of T measured at constant pressure p is presented in Fig. 5. No evidence for any phase transitions was observed down to 1.85 K. At 300 K the heat capacity attains a value of 123.5 J/molK which is close to the expected classical high- T Dulong-Petit lattice heat capacity value $C_V = 3nR = 15R = 124.7$ J/molK at constant volume V ,^{37,38} where R is the molar gas constant and $n = 5$ is the number of atoms per formula unit (f.u.) of SrCu_2As_2 . The inset in Fig. 5 shows the low- T data plotted as C_p/T versus T^2 allowing a conventional fit by

$$\frac{C_p(T)}{T} = \gamma + \beta T^2, \quad (1)$$

where γ is the Sommerfeld electronic linear specific heat coefficient and β is the coefficient of the Debye T^3 lattice heat capacity at low T . A linear fit of the data below 3.5 K according to Eq. (1), shown as the straight line in the inset of Fig. 5, gives the parameters

$$\begin{aligned} \gamma &= 2.2(2) \text{ mJ/mol K}^2 \\ \beta &= 0.47(3) \text{ mJ/mol K}^4. \end{aligned} \quad (2)$$

We obtained the value of the Debye temperature Θ_D from β using the relation³⁷

$$\Theta_D = \left(\frac{12\pi^4 N_A k_B n}{5\beta} \right)^{1/3}, \quad (3)$$

where N_A is Avogadro's number and k_B is Boltzmann's constant, yielding

$$\Theta_D = 274(6) \text{ K}. \quad (4)$$

The Sommerfeld coefficient γ can be used to estimate the density of states at the Fermi level $\mathcal{D}(E_F)$ for both spin directions according to³⁷

$$\gamma = \frac{\pi^2 k_B^2}{3} \mathcal{D}(E_F) (1 + \lambda_{e-ph}), \quad (5)$$

where λ_{e-ph} is the electron-phonon coupling constant which we set to zero and obtain a value

$$\mathcal{D}(E_F) = 0.93 \text{ states/eV f.u.} \quad (6)$$

for both spin directions. This value of $\mathcal{D}(E_F)$ is less than the value 1.53 states/eV f.u. for both spin directions predicted from the band structure calculations for SrCu_2As_2 .²⁹

The $\mathcal{D}(E_F)$ can be used to estimate the band effective mass m^* using the relation

$$\mathcal{D}(E_F) = N_{\text{band}} \left(\frac{m^* V_{\text{f.u.}} k_F}{\hbar^2 \pi^2} \right), \quad (7)$$

where $\mathcal{D}(E_F)$ is in units of states/erg f.u. with the quantities on the right-hand side in cgs units, k_F is the Fermi wave vector, $V_{\text{f.u.}}$ is the volume per formula unit and N_{band} is the number of degenerate bands at E_F with the same m^* and Fermi velocity v_F . The quantity in parentheses on the right-hand side corresponds to the single-band relation.³⁷ Further, using $k_F = m^* v_F / \hbar$, Eq. (7) can be rearranged to yield

$$\left(\frac{m^*}{m_e} \right)^2 = \frac{\hbar^3 \pi^2}{V_{\text{f.u.}} m_e^2 v_F} \frac{\mathcal{D}(E_F)}{N_{\text{band}}}, \quad (8)$$

where m_e is the free electron mass. Using the average value

$$\langle v_F \rangle = 2.7 \times 10^7 \text{ cm/s} \quad (9)$$

from the band structure calculation²⁹ and $V_{\text{f.u.}} = V_{\text{cell}}/Z$ where $Z = 2$ is the number of formula units per unit cell, we obtain

$$\frac{m^*}{m_e} = 1.86 \left[\frac{\mathcal{D}(E_F)}{N_{\text{band}}} \right]^{1/2}, \quad (10)$$

where $\mathcal{D}(E_F)$ is now in units of states/eV f.u. for both spin directions. The band structure calculations show that $N_{\text{band}} = 2$ for SrCu_2As_2 , but there are three distinct Fermi surfaces arising from the two bands.²⁹ Hence taking $N_{\text{band}} = 2$ or 3 and using $\mathcal{D}(E_F) = 0.93$ states/eV f.u. for both spin directions from Eq. (6), the effective mass estimated from Eq. (10) is

$$\begin{aligned} m^* &= 1.27 m_e & (N_{\text{band}} = 2) \\ m^* &= 1.04 m_e & (N_{\text{band}} = 3). \end{aligned} \quad (11)$$

The ratio $m^*/m_e \sim 1$ is consistent with the prediction²⁹ that SrCu_2As_2 is an *sp*-band metal.

The heat capacity data of a nonmagnetic metal over an extended T range can be approximated by

$$C_p(T) = \gamma T + n C_V \text{Debye}(T), \quad (12)$$

where γ is fixed to be the Sommerfeld electronic specific heat coefficient found above, $C_V \text{Debye}(T)$ is the Debye lattice heat capacity due to acoustic phonons at constant volume V per mole of atoms, and n is the number of atoms per f.u. ($n = 5$ here). The Debye function $C_V \text{Debye}(T)$ is given by³⁸

$$C_V \text{Debye}(T) = 9R \left(\frac{T}{\Theta_D} \right)^3 \int_0^{\Theta_D/T} \frac{x^4 e^x}{(e^x - 1)^2} dx. \quad (13)$$

The heat capacity data in Fig. 5 were least-squares fitted by Eqs. (12) and (13) over the T range 2–300 K using the Padé approximant function for $C_V \text{Debye}(T)$ developed by us in Ref. 39, with Θ_D being the only adjustable parameter. The solid curve in Fig. 5 represents the best fit of the experimental data in Fig. 5 by Eqs. (12) and (13), yielding $\Theta_D = 246(1)$ K. This value of Θ_D is different from the value of $\Theta_D = 274(6)$ K obtained in

TABLE IV: The linear specific heat coefficients γ and the coefficient β of the T^3 term in the low- T heat capacity, and the density of states at the Fermi energy $\mathcal{D}(E_F)$ for both spin directions for SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 single crystals. The Debye temperatures Θ_D obtained at low T and for all T from heat capacity measurements and the Debye temperature Θ_R obtained from fitting electrical resistivity data, respectively, are also listed.

Compound	γ (mJ/mol K ²)	β (mJ/mol K ⁴)	$\mathcal{D}(E_F)$ (states/eV f.u.)	Θ_D (K) from low- T	Θ_D (K) from all T	Θ_R (K) from $\rho(T)$
SrCu_2As_2	2.2(2)	0.47(3)	0.93	274(6)	246(1)	245(4)
SrCu_2Sb_2	3.9(2)	0.76(3)	1.65	234(3)	214(1)	153(1)
$\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$	2.3(2)	0.83(2)	0.97	227(2)	237(1)	225(6)
BaCu_2Sb_2	3.5(2)	0.65(2)	1.49	246(3)	204(1)	160(2)

Eq. (4) from the coefficient β deduced from the low- T heat capacity data. The difference between the two values may arise due to the approximations made in Debye theory that result in a T -dependent Θ_D , so the fit by Eq. (12) gives a value of Θ_D that is averaged over T . A contribution to the difference also comes from the fact that the heat capacity was measured at constant pressure whereas the Debye theory describes the lattice heat capacity at constant volume. The parameters obtained from our heat capacity fits are summarized in Table IV. Also listed is the Debye temperature Θ_R obtained from fitting our experimental $\rho(T)$ data for SrCu_2As_2 by the Bloch-Grüneisen model in Sec. IV C below.

B. Magnetization and Magnetic Susceptibility

The zero-field-cooled (ZFC) magnetic susceptibilities $\chi \equiv M/H$ of a SrCu_2As_2 single crystal as a function of T from 1.8 to 340 K in an applied magnetic field $H = 3.0$ T aligned along the c -axis (χ_c , $\mathbf{H} \parallel \mathbf{c}$) and in the ab -plane (χ_{ab} , $\mathbf{H} \perp \mathbf{c}$) are presented in Fig. 6, where M is the measured magnetization of the crystal. The χ has a negative sign and is anisotropic with $\chi_{ab} > \chi_c$ over the whole T range. This kind of anisotropy is common in the iron arsenide family; e.g., both BaFe_2As_2 (Ref. 40) and SrFe_2As_2 (Ref. 41) exhibit $\chi_{ab} > \chi_c$. The powder and temperature average of our anisotropic χ values in Fig. 6 is significantly more diamagnetic (negative) than the T -independent value between 80 and 400 K of $\chi = -5.4 \times 10^{-5} \text{ cm}^3/\text{mol}$ reported previously for a polycrystalline sample.³³ This difference may be due to a saturation magnetization of ferromagnetic (FM) impurities in the latter sample that was incompletely corrected for.

Upturns are observed in the $\chi(T)$ data in Fig. 6 at low T for both χ_{ab} and χ_c that are likely due to the presence of a small amount of saturable paramagnetic (PM) impurities as deduced from the $M(H)$ isotherm data discussed below. Since SrCu_2As_2 is weakly diamagnetic, even trace amounts of magnetic impurities can make significant contributions to the χ and M data. Therefore, a correction for the magnetic impurity contribution is necessary to determine the intrinsic magnetic behavior of the compound.

The isothermal M data for SrCu_2As_2 as a function of

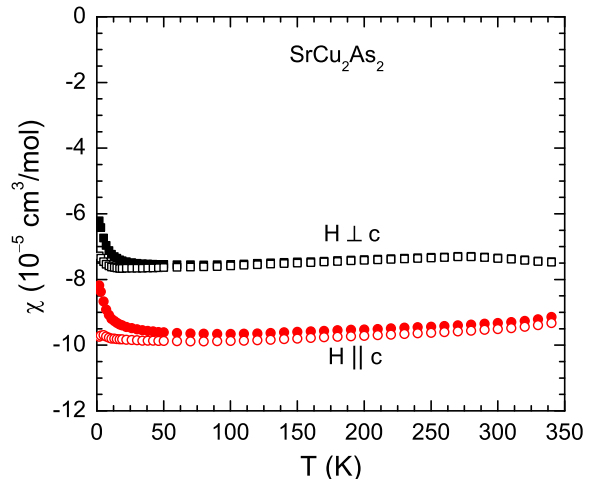


FIG. 6: (Color online) Zero-field-cooled magnetic susceptibility χ of a SrCu_2As_2 single crystal versus temperature T in the temperature range 1.8 – 350 K measured in a magnetic field of 3.0 T applied along the c -axis (χ_c , $\mathbf{H} \parallel \mathbf{c}$) and in the ab -plane (χ_{ab} , $\mathbf{H} \perp \mathbf{c}$) (solid symbols). The open symbols represent the intrinsic susceptibility of SrCu_2As_2 after correcting for the ferromagnetic and paramagnetic impurity contributions as described in the text.

H measured at eight temperatures between 1.8 and 300 K with $\mathbf{H}$ applied along the c -axis (M_c , $\mathbf{H} \parallel \mathbf{c}$) and in the ab -plane (M_{ab} , $\mathbf{H} \perp \mathbf{c}$) are presented in Fig. 7. The $M(H)$ data are diamagnetic and reveal anisotropic behavior with $M_{ab}(H) > M_c(H)$, which is consistent with the above observation $\chi_{ab} > \chi_c$. The presence of slight nonlinearities in the $M(H)$ isotherms at low fields, particularly at low T , reveals the presence of saturable ferromagnetic FM and/or paramagnetic PM impurities in the sample.

Since the $M(H)$ contribution of a FM impurity is typically nonlinear only at low fields $H \lesssim 1\text{--}2$ T one can estimate the FM impurity saturation magnetization M_s from the high-field $M(H)$ data. Furthermore, typical FM impurities have Curie temperatures significantly above room temperature, and saturable PM impurities do not show nonlinear $M(H)$ behaviors above ~ 25 K. We therefore determined the M_s of the FM impurities by

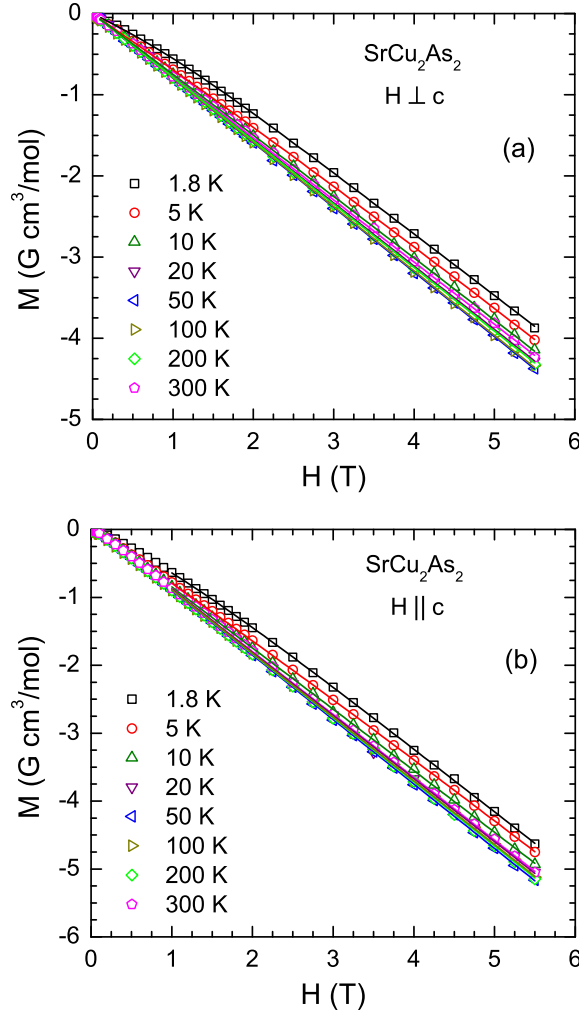


FIG. 7: (Color online) Isothermal magnetization M of a SrCu_2As_2 single crystal versus magnetic field H measured at the indicated temperatures for $\mathbf{H}$ applied (a) perpendicular to the c -axis (M_{ab} , $\mathbf{H} \perp \mathbf{c}$) and (b) along the c -axis (M_c , $\mathbf{H} \parallel \mathbf{c}$). The solid curves are fits by Eq. (15).

fitting the $M(H)$ data at $H \geq 2.0$ T for $T \geq 25$ K by

$$M(H) = M_s + \chi H, \quad (14)$$

where χ is the susceptibility of the sample for a particular field orientation that can still contain the contribution from paramagnetic PM impurities as discussed next. The M_s values obtained from the fits were found to be independent of T for $T \geq 25$ K to within the error bars. The values are listed in Table V. The M_s^c value corresponds to the saturation magnetization of only 4 molar ppm of Fe metal impurities.

The PM impurity contribution to M can be estimated by fitting the $M(H)$ data for each field direction by

$$M(T, H) = M_s + \chi_0 H + f_{\text{imp}} M_{s_{\text{imp}}} B_{S_{\text{imp}}}(x), \quad (15)$$

where M_s is the FM impurity saturation magnetization value found above, χ_0 is the intrinsic susceptibility of

TABLE V: Parameters obtained for SrCu_2As_2 and SrCu_2Sb_2 from fitting $M(H)$ isotherms at 1.8 K by Eqs. (14) and (15), where $\theta_{\text{imp}} \equiv 0$. Here M_s is the saturation magnetization of ferromagnetic impurities, χ_0 is the intrinsic susceptibility, and f_{imp} and S_{imp} are the molar fraction and spin of the paramagnetic impurities, respectively.

Compound	field direction	M_s ($\frac{\text{G cm}^3}{\text{mol}}$)	χ_0 ($10^{-5} \frac{\text{cm}^3}{\text{mol}}$)	$f_{\text{imp}} S_{\text{imp}}$ (10^{-5})
SrCu_2As_2	$H \perp c$	0.00(2)	-7.62(2)	3.05(8)
	$H \parallel c$	0.05(3)	-9.32(4)	4.1(2)
SrCu_2Sb_2	$H \perp c$	0.00(5)	-17.1(1)	10.9(3)
	$H \parallel c$	0.02(3)	-5.56(3)	2.2(1)

the compound, f_{imp} is the molar fraction of PM impurities, $M_{s_{\text{imp}}} = N_A g_{\text{imp}} \mu_B S_{\text{imp}}$ is the PM impurity saturation magnetization, N_A is Avogadro's number, μ_B is the Bohr magneton, and g_{imp} and S_{imp} are the spectroscopic splitting factor (g -factor) and the spin of the impurities, respectively. The Brillouin function $B_{S_{\text{imp}}}$ for the PM impurities is given by

$$B_{S_{\text{imp}}}(x) = \frac{1}{2S_{\text{imp}}} \left\{ (2S_{\text{imp}} + 1) \coth \left[(2S_{\text{imp}} + 1) \frac{x}{2} \right] - \coth \left(\frac{x}{2} \right) \right\}, \quad (16)$$

where

$$x \equiv \frac{g_{\text{imp}} \mu_B H}{k_B (T - \theta_{\text{imp}})}. \quad (17)$$

A Weiss temperature θ_{imp} is included in the Brillouin function in order to take weak interactions between PM impurity spins into account in a mean-field way. In particular, when $B_{S_{\text{imp}}}(x)$ is expanded to first order in x for $x \ll 1$, one obtains a Curie-Weiss law for the low-field susceptibility of the impurity spins with Weiss temperature θ_{imp} . In order to reduce the number of fitting parameters, the impurity g -factor was set to $g_{\text{imp}} = 2$ for this compound as well as for SrCu_2Sb_2 in Sec. VB below.

The solid curves in Fig. 7 are the fits of the $M(H)$ data by Eq. (15) that were obtained using the above M_s^{ab} and M_s^c values for $\mathbf{H} \perp \mathbf{c}$ and $\mathbf{H} \parallel \mathbf{c}$, respectively. Since M_s^{ab} is zero we fitted the $M(H)$ data for $\mathbf{H} \perp \mathbf{c}$ by Eq. (15) in the whole range $0 \leq H \leq 5.5$ T. However, since M_s^c is nonzero we fitted the $M(H)$ data for $\mathbf{H} \parallel \mathbf{c}$ only in the range $1.0 \leq H \leq 5.5$ T. We found that setting $\theta_{\text{imp}} = 0$ gives a good fit for both field directions, so in the final fits we set $\theta_{\text{imp}} \equiv 0$.

The parameter χ_0 and the product of the parameters f_{imp} and S_{imp} obtained from the fits of the $M(H)$ isotherms at 1.8 K for $\mathbf{H} \parallel \mathbf{c}$ and $\mathbf{H} \perp \mathbf{c}$ in Fig. 7 by Eq. (15) are listed in Table V. From Table V, both M_s and the product $f_{\text{imp}} S_{\text{imp}}$ are different for $\mathbf{H} \parallel \mathbf{c}$ compared with $\mathbf{H} \perp \mathbf{c}$, which indicates that the magnetizations of the FM and PM impurities are both anisotropic. The origins of these anisotropies are not clear.

From Eq. (15), the magnetic impurity contribution to the magnetization, for fields above the saturation field of about 1 T for the FM impurities, is

$$M_{\text{imp}}(H, T) = M_s + f_{\text{imp}} M_{s_{\text{imp}}} B_{S_{\text{imp}}}(x).$$

The $\chi(T) \equiv M(T)/H$ data in Fig. 6 were taken with $H = 3$ T. Therefore, this field was above the saturation field of the FM impurities and one can correct for the contributions of both the FM and PM impurities to obtain the intrinsic susceptibility versus T according to

$$\chi_0(T) = \frac{M(T) - M_{\text{imp}}(H, T)}{H}.$$

In this way we obtained the intrinsic $\chi_0(T)$ data shown as the open symbols in Fig. 6. The magnetic impurities are seen to have little influence on the measured susceptibility except below about 50 K where the PM impurity contribution to $M(T)$ becomes significant.

The largest value of $f_{\text{imp}} S_{\text{imp}} = 1.09 \times 10^{-4}$ in Table V, which is for χ_{ab} of SrCu_2Sb_2 (see below), corresponds to a very small concentration of paramagnetic impurities. For the worst case assumption $S_{\text{imp}} = 1/2$, the impurity concentration is $f_{\text{imp}} = 2.2 \times 10^{-4} = 0.022$ mol% = 220 molar ppm. If $S_{\text{imp}} = 5/2$, one obtains the five-times smaller value $f_{\text{imp}} = 4.4 \times 10^{-5} = 0.0044$ mol% = 44 molar ppm. The values of $M_s \leq 0.05$ G cm³/mol in Table V correspond to $M_s \leq 9.0 \times 10^{-6}$ μ_B /f.u. Thus if $S = 1/2$ and $g = 2$, this corresponds to a ferromagnetic molar impurity concentration of ≤ 9.0 molar ppm. On the other hand, if $S = 5/2$ and $g = 2$, this corresponds to a ferromagnetic molar impurity concentration of ≤ 1.8 molar ppm. As stated in Sec. II, the purity of the Sr used in the synthesis of the SrCu_2As_2 and SrCu_2Sb_2 crystals was 99.95 mol% (metals basis), i.e., containing 0.05 mol% of elemental metal impurities. Thus our values of $f_{\text{imp}} S_{\text{imp}}$ and M_s in Table V are consistent with (less than) the elemental metal impurity level supplied by the source of our Sr starting material. The nature of these magnetic impurities is unknown, and this information was not provided by the supplier of the Sr starting material.

The residual low- T upturns in χ_{ab} and χ_c in Fig. 6 (and in Fig. 10 below) after correction for the contribution of the paramagnetic impurities are very small and are most likely due to imperfect subtractions of the paramagnetic impurity contributions. The small changes in the magnitudes of χ between 300 and 350 K in Fig. 6 (and in Figs. 10 and 14 below) are believed to be experimental artifacts of our SQUID magnetometer. Such small changes are seen in many samples of different types that we have measured on this instrument in this T range. The origin of this systematic error is unknown.

The contributions to χ_0 of a nonmagnetic metal are

$$\chi_0 = \chi_{\text{core}} + \chi_{\text{VV}} + \chi_{\text{L}} + \chi_{\text{P}}, \quad (18)$$

where the first three terms comprise the orbital susceptibility contributions. Here χ_{core} is the diamagnetic susceptibility due to the localized core electrons, χ_{VV} is the

TABLE VI: Estimated contributions to the intrinsic angle- and temperature-averaged magnetic susceptibilities $\langle\chi_0\rangle$ of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 crystals in units of 10^{-5} cm³/mol. Here χ_{P} is the Pauli spin susceptibility of the conduction carriers, and the orbital susceptibility contributions are the diamagnetism χ_{core} of the atomic electron cores, the Landau diamagnetism χ_{L} of the conduction carriers and the Van Vleck paramagnetism χ_{VV} .

Compound	$\langle\chi_0\rangle$	χ_{core}	χ_{P}	χ_{L}	χ_{VV}
SrCu_2As_2	-8.25	-17.50	3.00	-0.62	6.87
SrCu_2Sb_2	-15.58	-20.79	5.33	-1.78	1.66
$\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$	-6.95	-18.03	3.14	-1.05	8.99
BaCu_2Sb_2	-8.02	-23.10	4.81	-1.60	11.9

paramagnetic Van Vleck susceptibility, and χ_{L} is the diamagnetic Landau susceptibility of the conduction carriers. The last term χ_{P} is the paramagnetic Pauli spin susceptibility of the conduction carriers.

The powder- and temperature-average (from 1.8 to 350 K) of χ_0 is $\langle\chi_0\rangle = (2\chi_{ab} + \chi_c)/3 = -8.25 \times 10^{-5}$ cm³/mol. Since our compounds are closer to being covalent metals than ionic metals, we used atomic diamagnetic values⁴² for χ_{core} to obtain $\chi_{\text{core}} = -1.75 \times 10^{-4}$ cm³/mol. The χ_{P} can be estimated from $\mathcal{D}(E_{\text{F}})$ using the relation⁴³

$$\chi_{\text{P}} = \mu_{\text{B}}^2 \mathcal{D}(E_{\text{F}}). \quad (19)$$

We then obtain $\chi_{\text{P}} = 3.00 \times 10^{-5}$ cm³/mol using $\mathcal{D}(E_{\text{F}}) = 0.98$ states/eV f.u. for both spin directions from Eq. (6). The χ_{L} can be estimated from the relation^{43,44}

$$\chi_{\text{L}} = -\frac{1}{3} \left(\frac{m_{\text{e}}}{m^*} \right)^2 \chi_{\text{P}}. \quad (20)$$

Using $m^* = 1.27 m_{\text{e}}$ from Eq. (11), one obtains $\chi_{\text{L}} = -0.62 \times 10^{-5}$ cm³/mol. One can then estimate the angle- and temperature-averaged χ_{VV} using Eq. (18) and the above values of χ_{core} , χ_{P} and χ_{L} , which give $\chi_{\text{VV}} = 6.87 \times 10^{-5}$ cm³/mol, a physically reasonable value. The above contributions to the average intrinsic magnetic susceptibility of SrCu_2As_2 are summarized in Table VI.

C. Electrical Resistivity Measurements and the Bloch-Grüneisen Model

The in-plane electrical resistivity ρ data for SrCu_2As_2 as a function of T are presented in Fig. 8. Metallic character is indicated from the positive temperature coefficient of $\rho(T)$. The relatively low value (for 122-type compounds) of the residual resistivity

$$\rho_0 \equiv \rho(T \rightarrow 0) = 9.3 \mu\Omega \text{ cm}$$

and a reasonably large residual resistivity ratio

$$\text{RRR} \equiv \frac{\rho(300 \text{ K})}{\rho(1.8 \text{ K})} \approx 6$$

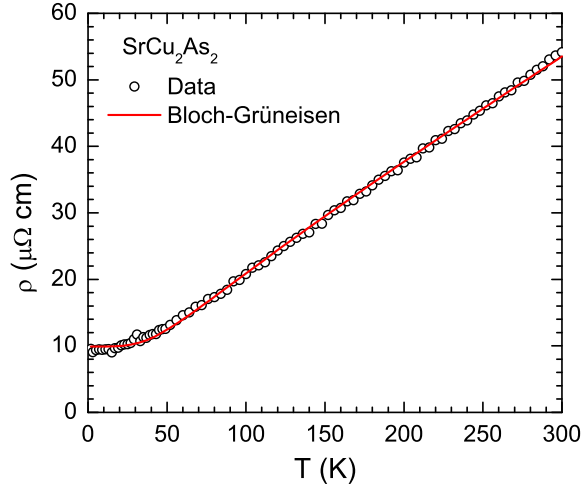


FIG. 8: (Color online) In-plane electrical resistivity ρ of a SrCu_2As_2 crystal versus temperature T . The red solid curve is the fit by the Bloch-Grüneisen model.

indicate that our crystal is of good quality.

We fitted the $\rho(T)$ data of SrCu_2As_2 by the Bloch-Grüneisen (BG) model that describes the electrical resistivity $\rho_{\text{BG}}(T)$ due to scattering of the conduction electrons by acoustic lattice vibrations in a monatomic metal according to⁴⁵

$$\rho_{\text{BG}}(T) = 4\mathcal{R}(\Theta_R) \left(\frac{T}{\Theta_R} \right)^5 \int_0^{\Theta_R/T} \frac{x^5}{(e^x - 1)(1 - e^{-x})} dx, \quad (21)$$

where Θ_R is the Debye temperature obtained from a fit of experimental resistivity data by the BG theory and the prefactor function $\mathcal{R}(\Theta_R)$ is given by

$$\mathcal{R}(\Theta_R) = \frac{\hbar}{e^2} \left[\frac{\pi^3 (3\pi^2)^{1/3} \hbar^2}{4n_{\text{cell}}^{2/3} a M k_B \Theta_R} \right]. \quad (22)$$

Here $\hbar$ is Planck's constant divided by 2π , e is the fundamental electric charge, n_{cell} is the number of conduction (valence) electrons per unit cell of volume a^3 containing one atom, M is the mass of the one atom per unit cell and k_B is Boltzmann's constant. The prefactor in Eq. (22) is $\hbar/e^2 = 4108.24 \, \Omega$ in SI units. Thus $\mathcal{R}(\Theta_R)$ can be found in the favored units of $\Omega \text{ cm}$ by expressing the quantities in square brackets in cgs units. The expression for $\mathcal{R}(\Theta_R)$ in Eq. (22) needs to be modified slightly according to Eq. (26) below in order to apply the BG theory to calculating the magnitude of the resistivity of polyatomic metals.

Even for simple s - or sp -metals it is usually not possible to accurately fit both the magnitude and T dependence of ρ by the BG model with Θ_R as the only adjustable parameter.⁴⁵ To fit the T dependence of ρ using the BG model we first calculate the BG prediction for $\rho(T = \Theta_R)$ from Eq. (21) as³⁹

$$\rho_{\text{BG}}(T = \Theta_R) = 0.9464635 \mathcal{R}(\Theta_R). \quad (23)$$

TABLE VII: Parameters associated with Bloch-Grüneisen fits to the resistivities ρ within the ab -plane of the listed single crystals. Here ρ_0 is the residual resistivity for $T \rightarrow 0$, Θ_R is the Debye temperature determined from resistivity measurements, $\rho(\Theta_R)$ is the fitted value of ρ at $T = \Theta_R$, and $\mathcal{R}(\Theta_R)$ is the quantity defined in Eq. (22) and is obtained from the fitted value of $\rho(\Theta_R)$ using Eq. (23).

Compound	ρ_0 ($\mu\Omega \text{ cm}$)	Θ_R (K)	$\rho(\Theta_R)$ ($\mu\Omega \text{ cm}$)	$\mathcal{R}(\Theta_R)$ ($\mu\Omega \text{ cm}$)
SrCu_2As_2	9.90(7)	245(4)	34.9(6)	36.9
SrCu_2Sb_2	13.64(1)	153(1)	13.8(1)	14.6
$\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$	17.65(5)	225(6)	16.5(4)	17.4
BaCu_2Sb_2	2.59(3)	160(2)	17.9(2)	18.9

Then the T dependence $\rho_{\text{BG}}(T)/\rho_{\text{BG}}(\Theta_R)$ is a function f of the ratio $y = T/\Theta_R$ and is given by Eqs. (21)–(23) as

$$f(y) = 4.226259 y^5 \int_0^{1/y} \frac{x^5}{(e^x - 1)(1 - e^{-x})} dx. \quad (24)$$

Now we can fit the experimental $\rho(T)$ data by the T dependence of the BG prediction according to³⁹

$$\rho(T) = \rho_0 + \rho(\Theta_R) f(T/\Theta_R), \quad (25)$$

where ρ_0 , $\rho(\Theta_R)$ and Θ_R are all independently adjustable fitting parameters. To carry out the fit of the experimental data by Eq. (25), we use an analytic Padé approximant function (a ratio of two polynomials in y^{-1}) that accurately fits $f(y)$ in Eq. (24). The numerical coefficients in the approximant are obtained by a high-accuracy nonlinear-least-squares fit of numerical values of $f(y)$ obtained from Eq. (24) by the Padé approximant as described in Ref. 39.

The solid red curve in Fig. 8 is the least-squares fit of the $\rho(T)$ data in Fig. 8 by Eqs. (24) and (25) using the Padé approximant function³⁹ in place of Eq. (24). The fit parameters obtained are $\rho_0 = 9.90(7) \, \mu\Omega \text{ cm}$, $\rho(\Theta_R) = 34.9(6) \, \mu\Omega \text{ cm}$, and $\Theta_R = 245(4) \text{ K}$. The value of Θ_R is identical within the errors to the value $\Theta_D = 246(1) \text{ K}$ obtained from the fit of heat capacity data over the whole measured T range by the Padé approximant for the Debye function (Table IV). The value of $\mathcal{R}(\Theta_R)$ can be calculated from the value of $\rho(\Theta_R)$ using Eq. (23), which gives $\mathcal{R}(\Theta_R) = 36.9 \, \mu\Omega \text{ cm}$. The parameters obtained from the fit of $\rho(T)$ for SrCu_2As_2 by the BG model are summarized in Table VII.

To compare our experimental value of $\rho(300 \text{ K})$ for SrCu_2As_2 with the value predicted by the Bloch-Grüneisen theory, it is necessary to slightly modify the expression for $\mathcal{R}(\Theta_R)$ in Eq. (22), which applies to monatomic metals, to allow application to polyatomic metals. Thus one obtains³⁹

$$\mathcal{R} = \frac{\hbar}{e^2} \left[\frac{\pi^3 (3\pi^2)^{1/3} \hbar^2}{4n_{\text{cell}}^{2/3} a k_B \Theta_R} \left(\frac{1}{M} \right)_{\text{ave}} \right], \quad (26)$$

where the variables have the same meaning as before, except that

$$\left(\frac{1}{M}\right)_{\text{ave}} = \frac{N_A}{n} \sum_{i=1}^n \frac{1}{M_i} \quad (27)$$

is the average inverse mass of the atoms in the compound, n is the number of atoms per f.u. and M_i is the atomic weight of element i . In this case, the equivalent lattice parameter of a primitive cubic unit cell containing one atom is $a = [V_{\text{cell}}/(nZ)]^{1/3}$ ($nZ = 10$ here) because there are $Z = 2$ formula units of ACu_2X_2 , with $n = 5$ atoms per formula unit, per body-centered tetragonal unit cell with volume V_{cell} given in Table II.

The number of current carriers per atom n_{cell} in Eq. (26) can be estimated from the band theory value²⁹ of v_F . Since $m^*v_F = \hbar k_F$, and using the one-band relation³⁷ $k_F = (3\pi^2 n^*)^{1/3}$ where n^* is the carrier density per band, one obtains

$$n^* = \frac{1}{3\pi^2} \left(\frac{m^*v_F}{\hbar} \right)^3 = 8.78 \times 10^{20} \text{ cm}^{-3}, \quad (28)$$

where to obtain the second equality we used the value of $\langle v_F \rangle$ given in Eq. (9) and the value of m^* given in Eq. (11). This gives

$$n_{\text{cell}} = N_{\text{band}} n^* \frac{V_{\text{cell}}}{nZ} = 0.0327. \quad (29)$$

Inserting this value of n_{cell} and the value $\Theta_R = 245$ K from Table IV into Eq. (26) we obtain $\mathcal{R}(\Theta_R) = 10.0 \mu\Omega \text{ cm}$. The value of $\rho(300 \text{ K})$ predicted by the BG model is then numerically calculated from Eq. (21) to be $\rho(300 \text{ K}) = 21.7 \mu\Omega \text{ cm}$. The measured value $\rho(300 \text{ K}) = 54 \mu\Omega \text{ cm}$ from Fig. 8 is a factor of 2.5 larger than this theoretical value. However, this should be considered to be satisfactory agreement in view of the even larger factors of 3 to 8 discrepancy between experiment and theory for other *sp*-metals such as Au, Be, Cd, Zn, Mg, Al and In.⁴⁵ Such discrepancies can be attributed at least in part to deviations of the shapes of the Fermi surfaces from the spherical shape assumed in the Bloch-Grüneisen theory.

We conclude that both the magnitude and T dependence of the in-plane electrical resistivity of SrCu_2Sb_2 are adequately fitted over the entire T range 1.8–300 K by the Bloch-Grüneisen model in which the T -dependence of the resistivity arises solely from electron-phonon scattering.

V. PHYSICAL PROPERTIES OF SrCu_2Sb_2 CRYSTALS

A. Heat Capacity

The $C_p(T)$ data for SrCu_2Sb_2 are presented in Fig. 9 for $1.8 \leq T \leq 300$ K. The $C_p(T)$ data do not show any

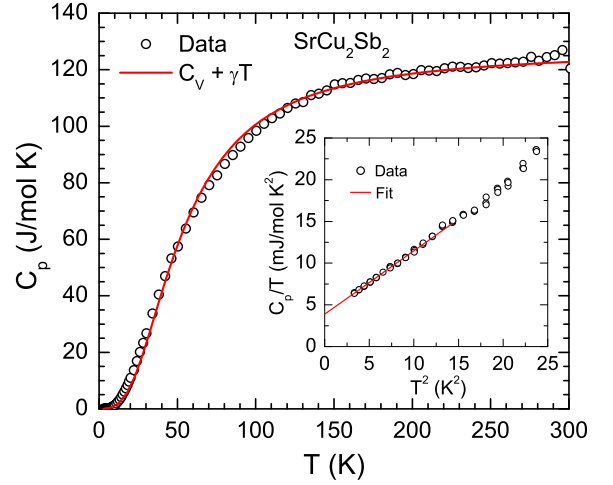


FIG. 9: (Color online) Heat capacity C_p of a SrCu_2Sb_2 single crystal versus temperature T . The solid red curve is a fit of the data by the sum of the contributions from the Debye lattice heat capacity $C_{V \text{ Debye}}(T)$ and predetermined electronic heat capacity γT according to Eq. (12). Inset: C_p/T vs. T^2 below 5 K. The straight line is the fit by $C_p/T = \gamma + \beta T^2$ [Eq. (1)] for $1.8 \text{ K} \leq T \leq 3.5 \text{ K}$.

evidence for any phase transitions over this T range. Like SrCu_2As_2 , the value of $C_p(T = 300 \text{ K}) \approx 124 \text{ J/mol K}$ for SrCu_2Sb_2 is very close to the expected classical Dulong-Petit value $C_V = 124.7 \text{ J/mol K}$. A fit of the low- T $C_p(T)$ data below 3.5 K by Eq. (1) (solid line in the inset of Fig. 9) yields $\gamma = 3.9(2) \text{ mJ/mol K}^2$ and $\beta = 0.76(3) \text{ mJ/mol K}^4$. Using Eq. (5), the γ value gives $\mathcal{D}(E_F) = 1.65$ states/eV f.u. for both spin directions which is larger than that of SrCu_2As_2 . The Debye temperature determined using Eq. (3) is $\Theta_D = 234(3) \text{ K}$.

A fit of the $C_p(T)$ data over the whole T range 1.8–300 K by the sum of an electronic contribution γT , with γ fixed at the above value, and the Debye lattice heat capacity contribution via Eqs. (12) and (13) gives $\Theta_D = 214(1) \text{ K}$ which is somewhat smaller than the above value $\Theta_D = 234(3) \text{ K}$ obtained from a fit to the low- T $C_p(T)$ data only. The solid curve in Fig. 9 is the fit of the data by the sum of electronic γT and Debye lattice heat capacity terms where for the latter we used our Padé approximant function.³⁹ The parameters obtained from our fits to $C_p(T)$ for SrCu_2Sb_2 are summarized in Table IV.

B. Magnetization and Magnetic Susceptibility

The ZFC anisotropic $\chi(T)$ data of a SrCu_2Sb_2 single crystal in $H = 3.0 \text{ T}$ are presented in Fig. 10 together with the intrinsic χ values after correction for PM and FM impurity contributions as described below. Similar to the case of SrCu_2As_2 , the χ has negative values. However, the χ anisotropy in SrCu_2Sb_2 is different from that of SrCu_2As_2 . Here it is clear that $\chi_c > \chi_{ab}$ instead of $\chi_c < \chi_{ab}$. The reason for this large qualitative difference

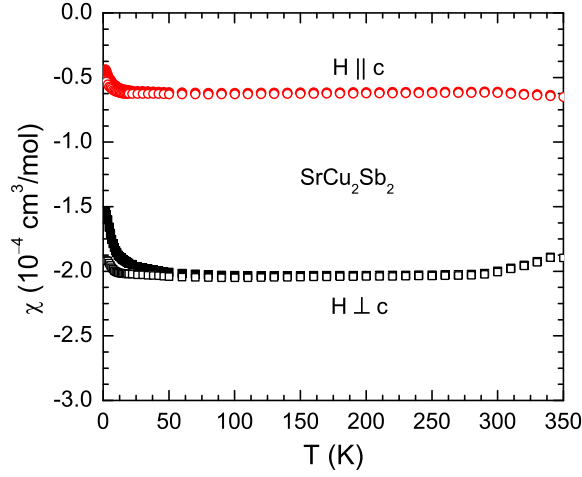


FIG. 10: (Color online) Zero-field-cooled magnetic susceptibility $\chi \equiv M/H$ of a SrCu_2Sb_2 single crystal versus temperature T in the temperature range 1.8–350 K measured in a magnetic field of 3.0 T applied along the c -axis (χ_c , $\mathbf{H} \parallel \mathbf{c}$) and in the ab -plane (χ_{ab} , $\mathbf{H} \perp \mathbf{c}$) (solid symbols). The open symbols are the intrinsic susceptibility of SrCu_2Sb_2 after correcting for ferromagnetic and paramagnetic impurity contributions.

in the magnetic anisotropy between the two compounds is not known in detail but is probably associated with the differences between the crystal structures of the two compounds.

The anisotropic isothermal $M(H)$ data for SrCu_2Sb_2 at different T are presented in Fig. 11. The $M(H)$ curves exhibit anisotropic diamagnetic behaviors with $M_c(H) > M_{ab}(H)$, as expected from the $\chi(T) \equiv M(T)/H$ data in Fig. 10. The contributions from FM and PM impurities that cause the slight nonlinearities in the $M(H)$ isotherms at low fields were estimated by fitting the $M(H)$ data by Eqs. (14) and (15). The M_s values were determined by fitting the $M(H)$ data above 2.0 T and at $T \geq 25$ K by Eq. (14). These values were found to be independent of T . The fitting parameters for both $M_{ab}(H)$ and $M_c(H)$ isotherms at 1.8 K are listed in Table V where we found that good fits are obtained using $\theta_{\text{imp}} = 0$ for both data sets. The fits by Eq. (15) are shown as the solid curves in Fig. 11. Similar to the case of SrCu_2As_2 , both M_s and the product $f_{\text{imp}}S_{\text{imp}}$ have different values for $\mathbf{H} \perp \mathbf{c}$ and $\mathbf{H} \parallel \mathbf{c}$, again indicating that the magnetizations of the FM and PM impurities in SrCu_2Sb_2 are anisotropic. The $M(H)$ isotherms at the other (higher) T were fitted using the values of f_{imp} and S_{imp} obtained from the 1.8 K $M(H)$ fits in order to extract the intrinsic anisotropic susceptibilities. We have corrected the measured susceptibility data for these FM and PM impurity contributions, and the resulting intrinsic susceptibilities are shown by open symbols in Fig. 10. There are no significant differences between the uncorrected and corrected data above 50 K. For $T \lesssim 50$ K, the PM impurity Curie-Weiss-like contribution is nearly eliminated in the corrected data, yielding an intrinsic susceptibility that is

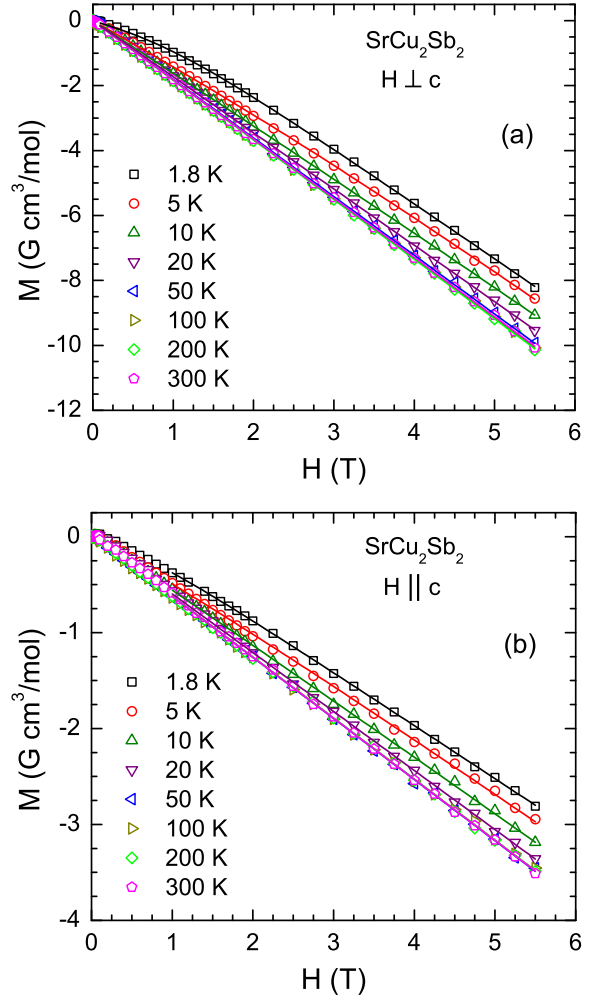


FIG. 11: (Color online) Isothermal magnetization M of a SrCu_2Sb_2 single crystal versus magnetic field H measured at the indicated temperatures for $\mathbf{H}$ applied (a) in the ab -plane (M_{ab} , $\mathbf{H} \perp \mathbf{c}$) and (b) along the c -axis (M_c , $\mathbf{H} \parallel \mathbf{c}$). The solid curves represent fits by Eq. (15) with the parameters in Table V, where $\theta_{\text{imp}} = 0$ was used for the fits.

nearly independent of T , as expected. There is a 10% discrepancy between the measured value of χ_{ab} (Fig. 10) and that obtained from the high-field ($H \geq 2$ T) slopes of the $M(H)$ isotherms for $\mathbf{H} \perp \mathbf{c}$ [Fig. 11(b)]. The reason for this discrepancy is not known, but it has no significant influence on our discussions or conclusions.

The powder- and temperature-average of the intrinsic magnetic susceptibility is $\langle \chi_0 \rangle = -1.56 \times 10^{-4} \text{ cm}^3/\text{mol}$. The different contributions to this averaged intrinsic susceptibility were estimated in the same way as for SrCu_2As_2 in Sec. IV B above. The diamagnetic core susceptibility is estimated as $\chi_{\text{core}} = -2.08 \times 10^{-4} \text{ cm}^3/\text{mol}$ using the atomic diamagnetic susceptibilities.⁴² From Eq. (19), the Pauli susceptibility is $\chi_{\text{P}} = 5.33 \times 10^{-5} \text{ cm}^3/\text{mol}$ using $\mathcal{D}(E_{\text{F}}) = 1.65 \text{ states/eV f.u.}$ for both spin directions determined above from the γ value. The $\chi_{\text{L}} = -1.78 \times 10^{-5} \text{ cm}^3/\text{mol}$ was obtained by tak-

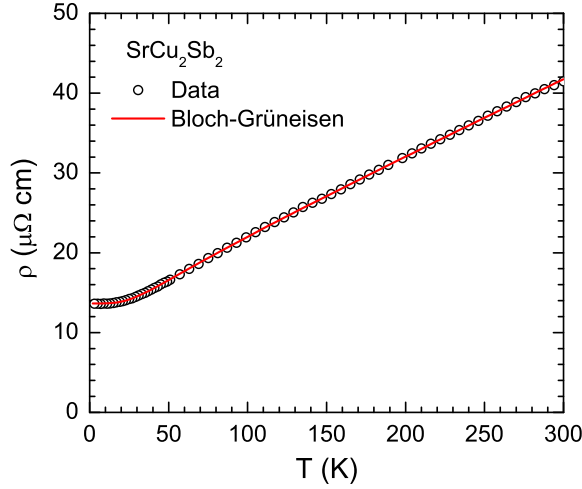


FIG. 12: (Color online) In-plane electrical resistivity ρ of a SrCu_2Sb_2 single crystal versus temperature T . The solid curve is a fit by the Bloch-Grüneisen model.

ing $m^* = m_e$ in Eq. (20). The Van Vleck susceptibility is then calculated from Eq. (18) to be $\chi_{\text{VV}} = 1.66 \times 10^{-5} \text{ cm}^3/\text{mol}$. These magnetic susceptibility contributions are summarized in Table VI.

The powder-averaged χ of SrCu_2Sb_2 is significantly more negative than that of SrCu_2As_2 , probably due at least in part to the larger χ_{core} of Sb compared to that of As. On the other hand, the magnitude of the anisotropy of χ is much larger in SrCu_2Sb_2 than in SrCu_2As_2 , for reasons that are not clear to us.

C. Electrical Resistivity

The in-plane $\rho(T)$ data for SrCu_2Sb_2 are presented in Fig. 12. The T dependence of ρ indicates metallic behavior with a residual resistivity $\rho_0 = 13.6 \mu\Omega \text{ cm}$ at 1.8 K and $\text{RRR} \approx 3$. The $\rho(T)$ of SrCu_2Sb_2 was analyzed using the Bloch-Grüneisen model. A least-squares fit by Eqs. (24) and (25) using our Padé approximant function³⁹ is shown as the red solid curve in Fig. 12. The fit parameters are $\rho_0 = 13.64(1) \mu\Omega \text{ cm}$, $\rho(\Theta_R) = 13.8(1) \mu\Omega \text{ cm}$ and $\Theta_R = 153(1) \text{ K}$. Using Eq. (23), one obtains $\mathcal{R}(\Theta_R) = 14.6 \mu\Omega \text{ cm}$. These parameters are summarized in Table VII.

VI. PHYSICAL PROPERTIES OF ORIENTED $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ CRYSTALS

A. Heat Capacity

The $C_p(T)$ data for $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ are presented in Fig. 13. Like SrCu_2As_2 and SrCu_2Sb_2 , the $C_p(T)$ data of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ reveal no evidence of any phase transitions. The $C_p(T = 300 \text{ K}) =$

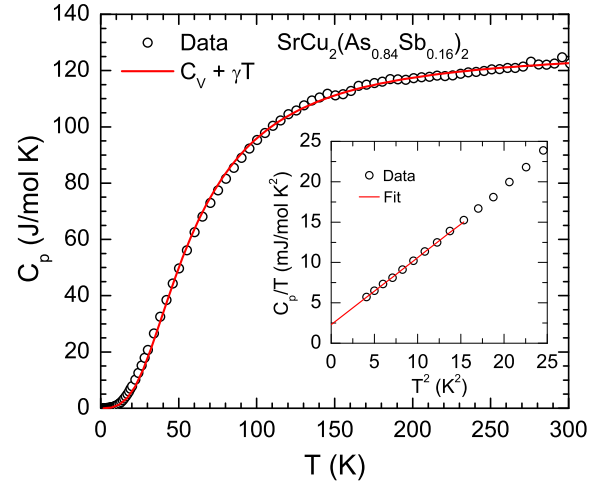


FIG. 13: (Color online) Heat capacity C_p of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ versus temperature T . The solid red curve is a fit of the data by the sum of the contributions from the Debye lattice heat capacity $C_{\text{V Debye}}(T)$ and pre-determined electronic heat capacity γT according to Eq. (12). Inset: C_p/T vs. T^2 below 5 K. The straight line is a fit by $C_p/T = \gamma + \beta T^2$ [Eq. (1)] for $2.0 \text{ K} \leq T \leq 3.5 \text{ K}$.

122.8 J/molK is again close to the Dulong-Petit value $C_V = 124.7 \text{ J/molK}$. From a linear fit of C_p/T vs. T^2 data below 3.5 K by Eq. (1) (solid red line in the inset of Fig. 13), we obtained $\gamma = 2.3(2) \text{ mJ/molK}^2$ and $\beta = 0.83(2) \text{ mJ/molK}^4$. The value of γ yields $\mathcal{D}(E_F) = 0.97 \text{ states/eV f.u.}$ for both spin directions from Eq. (5) and the value of β gives $\Theta_D = 227(2) \text{ K}$ from Eq. (3). A value $\Theta_D = 237(1) \text{ K}$ is obtained from a fit of the $C_p(T)$ data by the Debye lattice heat capacity model [Eqs. (12) and (13)] over the T range $1.8 \leq T \leq 300 \text{ K}$ as shown by the solid red curve in Fig. 13. This value is similar to the value obtained from the low- T fit. The above specific heat parameters are compared in Table IV with those of the other three compounds studied here.

B. Magnetization and Magnetic Susceptibility

The anisotropic ZFC $\chi(T)$ data of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ in $H = 3.0 \text{ T}$ are presented in Fig. 14. Like SrCu_2As_2 and SrCu_2Sb_2 , the χ of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ is diamagnetic. As can be seen from Fig. 14, $\chi_{ab} > \chi_c$, similar to the case of SrCu_2As_2 but in contrast to that of SrCu_2Sb_2 . Thus the anisotropy seems to be a characteristic of the crystal structure, since the structure of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ is the same as that of SrCu_2As_2 but different from that of SrCu_2Sb_2 .

The anisotropic isothermal $M(H)$ data for $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ at different T are presented in Fig. 15. The $M(H)$ curves exhibit anisotropic behavior with $M_{ab} > M_c$, consistent with the $\chi(T) \equiv M(T)/H$ data discussed above. Furthermore, we observe that the M is almost proportional to H at each T , indicating

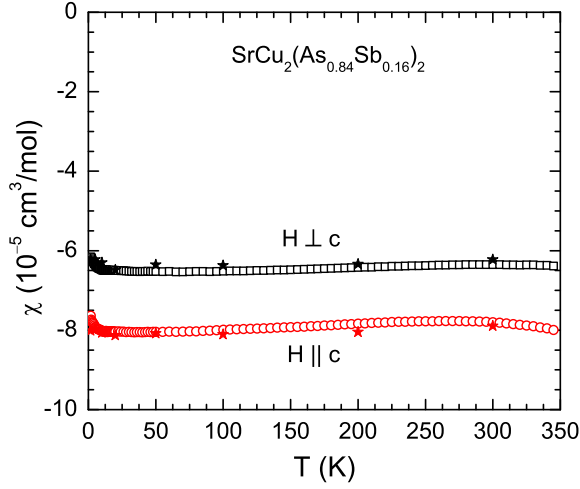


FIG. 14: (Color online) Zero-field-cooled magnetic susceptibility $\chi \equiv M/H$ of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ versus temperature T in a magnetic field $H = 3.0$ T applied along the c -axis (χ_c , $\mathbf{H} \parallel \mathbf{c}$) and in the ab -plane (χ_{ab} , $\mathbf{H} \perp \mathbf{c}$). The solid stars represent the intrinsic susceptibility of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ obtained from the high-field slopes of $M(H)$ isotherms.

only very small amounts of FM and PM impurities in the sample. The intrinsic χ_0 values obtained from the high-field ($H \geq 2$ T) slopes of the $M(H)$ isotherms are shown as solid stars in Fig. 14. The powder- and temperature-average $\langle \chi_0 \rangle$ of χ_0 and the different contributions χ_{core} , χ_{P} , χ_{L} and χ_{VV} to $\langle \chi_0 \rangle$ estimated in the same ways as in section IV are presented in Table VI. Interestingly, the $\langle \chi_0 \rangle$ of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ is not intermediate between those of SrCu_2As_2 and SrCu_2Sb_2 .

C. Electrical Resistivity

The in-plane $\rho(T)$ data for $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ are presented in Fig. 16. Like SrCu_2As_2 and SrCu_2Sb_2 , the $\rho(T)$ of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ exhibits metallic behavior with $\rho_0 = 17.6 \mu\Omega \text{ cm}$, which is the largest value among the four compounds studied here (see Table VII). The $\text{RRR} \approx 2$ is smaller than those of the end-point compounds SrCu_2As_2 ($\text{RRR} \approx 6$) and SrCu_2Sb_2 ($\text{RRR} \approx 3$) as expected from the atomic disorder on the As/Sb sublattices, and also of BaCu_2Sb_2 ($\text{RRR} \approx 15$, see below) with yet another structure. The large value of ρ_0 and the low RRR value for $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ are consistent with this compound being an sp -metal because the conduction carriers evidently strongly sense the atomic disorder on the As/Sb sublattices as they hop along these sublattices. An analysis of the $\rho(T)$ data of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ using the Bloch-Grüneisen model in Sec. IV C (solid curve in Fig. 16) gives $\rho_0 = 17.65(5) \mu\Omega \text{ cm}$, $\rho(\Theta_R) = 16.5(4) \mu\Omega \text{ cm}$, $\Theta_R = 225(6)$ K, and using Eq. (23), $\mathcal{R}(\Theta_R) = 17.4 \mu\Omega \text{ cm}$. These parameters are compared in Table VII with those obtained for the other three compounds studied here.

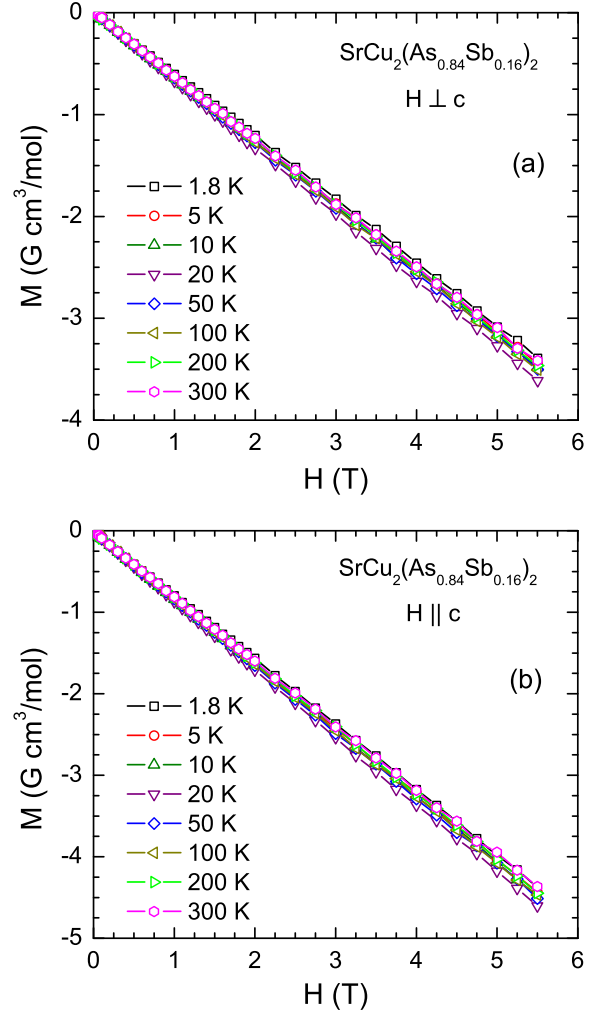


FIG. 15: (Color online) Isothermal magnetization M of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ versus magnetic field H measured at the indicated temperatures for $\mathbf{H}$ applied (a) in the ab -plane (M_{ab} , $\mathbf{H} \perp \mathbf{c}$) and (b) along the c -axis (M_c , $\mathbf{H} \parallel \mathbf{c}$).

VII. PHYSICAL PROPERTIES OF BaCu_2Sb_2 CRYSTALS

A. Heat Capacity

The $C_p(T)$ data for a BaCu_2Sb_2 crystal are presented in Fig. 17. The data reveal no evidence for any phase transitions. The data exhibit a saturation value of ~ 125 J/molK near room temperature which is close to the expected classical Dulong-Petit value of $C_V = 124.7$ J/molK. The origin of the weak upturn in $C_p(T)$ above 250 K is unknown and may be spurious, perhaps arising from a small inaccuracy in the high- T addenda calibration. We obtained the coefficients $\gamma = 3.5(2)$ mJ/molK² and $\beta = 0.65(2)$ mJ/molK⁴ from a linear fit of the low- T C_p/T vs. T^2 data below 3.5 K by Eq. (1) which is shown as the solid straight line in the inset of Fig. 17. The γ value and Eq. (5) yield $\mathcal{D}(E_F) =$

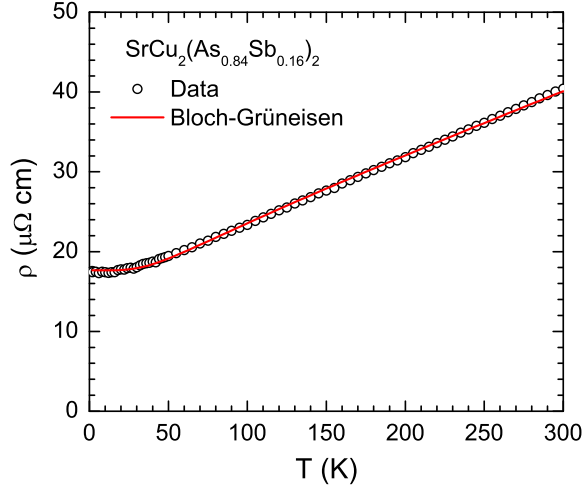


FIG. 16: (Color online) In-plane electrical resistivity ρ of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ versus temperature T . The solid curve is a fit by the Bloch-Grüneisen model.

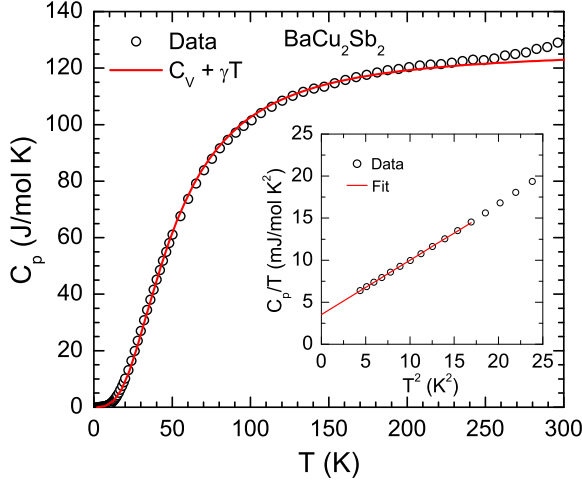


FIG. 17: (Color online) Heat capacity C_p of a BaCu_2Sb_2 single crystal versus temperature T . The solid red curve is a fit of the data by the sum of the contributions from the Debye lattice heat capacity $C_{\text{v Debye}}(T)$ and predetermined electronic heat capacity γT according to Eq. (12). Inset: C_p/T vs. T^2 below 5 K. The straight line is a fit by Eq. (1) for $2.0 \text{ K} \leq T \leq 3.5 \text{ K}$.

1.49 states/eV f.u. for both spin directions. The β and Eq. (3) yield $\Theta_D = 246(3) \text{ K}$. From a fit of the $C_p(T)$ data over the full T range by a sum of electronic and lattice contributions via Eqs. (12) and (13), we obtained a good fit using $\Theta_D = 204(1) \text{ K}$ as shown by the solid red curve in Fig. 17. These specific heat parameters are summarized in Table IV.

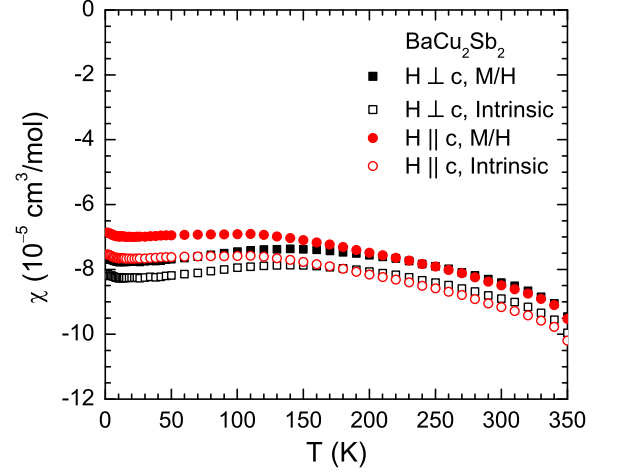


FIG. 18: (Color online) Zero-field-cooled magnetic susceptibility $\chi \equiv M/H$ of a BaCu_2Sb_2 single crystal versus temperature T measured in $H = 3.0 \text{ T}$ applied along the c -axis (χ_c , $\mathbf{H} \parallel \mathbf{c}$) and in the ab -plane (χ_{ab} , $\mathbf{H} \perp \mathbf{c}$) (solid symbols). The intrinsic susceptibilities after correcting for the small ferromagnetic impurity contributions are shown as open symbols.

B. Magnetization and Magnetic Susceptibility

The anisotropic $\chi(T)$ data of a BaCu_2Sb_2 single crystal in $H = 3.0 \text{ T}$ are plotted in Fig. 18. Like the other three compounds, the susceptibility is diamagnetic over the whole T range. The data are weakly T -dependent. A weak anisotropy is seen below $\sim 170 \text{ K}$ with $\chi_c > \chi_{ab}$ as in SrCu_2Sb_2 .

The $M(H)$ isotherms at different T are shown for BaCu_2Sb_2 in Fig. 19. Consistent with the $\chi(T)$ results in Fig. 18, the $M(H)$ curves of BaCu_2Sb_2 exhibit weakly anisotropic diamagnetic behavior with $M_c(H) > M_{ab}(H)$. The isotherms provide evidence for the presence of FM impurities but no evidence for saturable PM impurities in the sample. In order to obtain the intrinsic χ the $M(H)$ isotherms at each T were fitted by Eq. (14) at high fields $H \geq 2 \text{ T}$ and the resulting T -independent FM impurity contributions ($M_s^{ab} = 0.15 \text{ G cm}^3/\text{mol}$ and $M_s^c = 0.20 \text{ G cm}^3/\text{mol}$) were subtracted from the $M(T)$ measured at $H = 3 \text{ T}$. The different values of M_s^{ab} and M_s^c suggest an anisotropic FM impurity contribution. To give the scale of the FM impurity magnetization, the above value $M_s^{ab} = 0.15 \text{ G cm}^3/\text{mol}$ is equivalent to the magnetization contribution from 12 molar ppm of Fe metal impurities. The intrinsic anisotropic susceptibilities obtained after subtracting the FM impurity contributions are shown by open symbols in Fig. 18. The corrections for the FM impurities are seen to be rather small.

We have estimated the different contributions to the intrinsic χ of BaCu_2Sb_2 using the same methods as for the previous three compounds. The powder- and temperature-average over the T range 10 to 100 K is

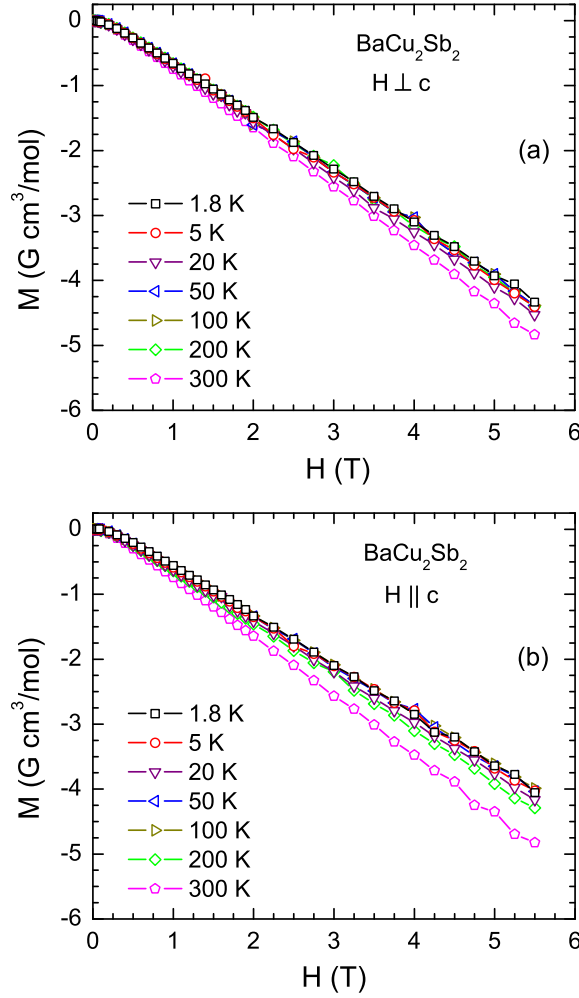


FIG. 19: (Color online) Isothermal magnetization M of a BaCu_2Sb_2 single crystal versus magnetic field H measured at the indicated temperatures for $\mathbf{H}$ applied (a) in the ab -plane (M_{ab} , $\mathbf{H} \perp \mathbf{c}$) and (b) along the c -axis (M_c , $\mathbf{H} \parallel \mathbf{c}$).

$\langle \chi_0 \rangle = -8.02 \times 10^{-5} \text{ cm}^3/\text{mol}$, and we infer $\chi_{\text{core}} = -2.31 \times 10^{-4} \text{ cm}^3/\text{mol}$, $\chi_P = 4.81 \times 10^{-5} \text{ cm}^3/\text{mol}$, and $\chi_L = -1.60 \times 10^{-5} \text{ cm}^3/\text{mol}$ (using $m^* = m_e$ in Eq. 20). We thus obtain $\chi_{\text{VV}} = 1.19 \times 10^{-4} \text{ cm}^3/\text{mol}$ from Eq. (18). A comparison of χ_{VV} with those of the other compounds (Table VI) suggests that χ_{VV} is largest in BaCu_2Sb_2 .

C. Electrical Resistivity

The $\rho(T)$ data for BaCu_2Sb_2 are presented in Fig. 20. The $\rho(T)$ exhibits metallic behavior with $\rho_0 = 2.5 \mu\Omega \text{ cm}$ at 1.8 K and $\text{RRR} \approx 15$, indicating that this crystal has the highest perfection of the four compounds studied here. An analysis of the $\rho(T)$ data in terms of the Bloch-Grüneisen model in Eq. (25) yielded a good fit with $\rho_0 = 2.59(3) \mu\Omega \text{ cm}$, $\rho(\Theta_R) = 17.9(2) \mu\Omega \text{ cm}$, $\Theta_R = 160(2) \text{ K}$, and using Eq. (23), $\mathcal{R}(\Theta_R) = 18.9 \mu\Omega \text{ cm}$. The fit is

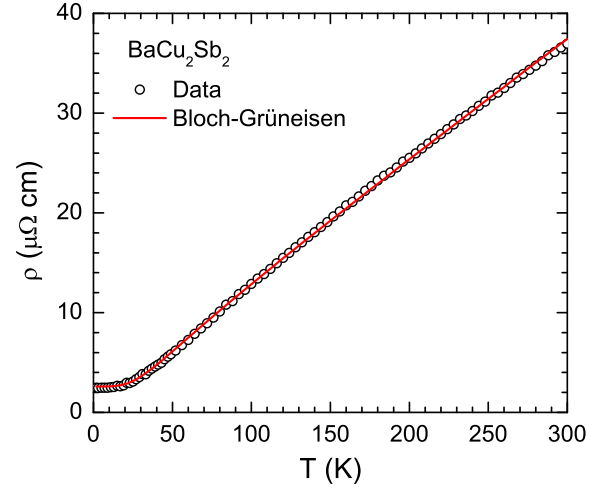


FIG. 20: (Color online) In-plane electrical resistivity ρ of a BaCu_2Sb_2 single crystal versus temperature T . The solid red curve is a fit by the Bloch-Grüneisen model.

shown as the solid red curve in Fig. 20. The fit parameters are summarized in Table VII for comparison with those of the other samples.

VIII. DISCUSSION

The electronic and magnetic properties of SrCu_2As_2 , SrCu_2Sb_2 , $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ and BaCu_2Sb_2 indicate that they are all nonmagnetic sp -band metals. The magnetic susceptibilities show temperature-independent diamagnetism and the heat capacities show small Sommerfeld electronic specific heat coefficients, both indicative of small densities of states at the Fermi energy. The electrical resistivities show no evidence for a T^2 term that might indicate significant d -electron scattering, and instead are all well-described by the Bloch-Grüneisen theory for scattering of sp -band electrons by longitudinal acoustic lattice vibrations.

For SrCu_2As_2 , our results are consistent with the band structure calculations for ThCr_2Si_2 -type SrCu_2As_2 and BaCu_2As_2 .²⁹ According to these calculations, the Cu $3d$ bands are centered about 3 eV below E_F and are completely occupied, with little Cu $3d$ character in the bands at E_F . The same behavior occurs in Cu metal, where the Cu $3d$ bands are centered 3.4 eV below E_F with a total $3d$ -band half-width of 1.4 eV.⁴⁶ The band calculations thus indicate that SrCu_2As_2 and BaCu_2As_2 are sp -band metals like Cu metal.²⁹

In a chemical picture the Cu atoms in these compounds have a $3d^{10}$ electronic configuration with a filled d -shell and a formal oxidation state of Cu^{+1} , where the Cu $4s^1$ valence electrons are itinerant. Assuming Cu^{+1} , Sr^{+2} and Ba^{+2} oxidation states in $(\text{Sr}, \text{Ba})\text{Cu}_2\text{As}_2$ yields an unusual oxidation state of As^{-2} for the As atoms, in contrast to the oxidation states Fe^{+2} and As^{-3} in

(Ca,Sr,Ba)Fe₂As₂.¹¹ This in turn suggests the presence of a covalent bond between the As atoms in adjacent layers that are directly above/below each other along the *c*-axis [see Fig. 4(a)], i.e., $\text{As}^{-2} \equiv [\text{As}-\text{As}]^{-4/2}$. Such covalent interlayer pnictogen bonding has been known since the 1980's for transition metal phosphides with the ThCr₂Si₂ structure.^{47–49} The variable degree of P–P covalent bonding in those compounds is reflected in a variable interlayer P–P distance $d_{\text{P-P}}$ and a resulting variable *c/a* ratio.⁵⁰ Notably, first-order transitions with increasing pressure between non-bonding and partially or fully bonding interplane P–P linkages were found for SrRh₂P₂ (Refs. 51, 52) and SrNi₂P₂.⁵³

In the recent field of iron arsenide and chalcogenide high-*T_c* superconductivity,¹¹ Kreyssig, Goldman et al.^{54,55} discovered a strong decrease in the *c*-axis lattice parameter and unit cell volume of ThCr₂Si₂-type CaFe₂As₂ in a first-order transition with increasing pressure *p* and dubbed this phase a “collapsed tetragonal” (cT) phase, as opposed to the ambient *p* (uncollapsed) tetragonal (T) phase. The T to cT transition occurs with increasing *p* at 0.4 GPa at low *T*, increasing to 1.7 GPa at 300 K.⁵⁵ This first-order T to cT phase transition can be viewed as resulting from the discontinuous creation with increasing *p* of covalent As–As interlayer bonds,⁵⁵ as occurs at ambient *p* or with increasing *p* in some ThCr₂Si₂-type phosphides as discussed above. The “cT” terminology has been widely adopted by the community working on iron arsenide superconductors.

The work by Kreyssig, Goldman et al.^{54,55} motivated many additional experimental and theoretical studies of the occurrence and properties of the cT phase in ThCr₂Si₂-type iron arsenides. A synchrotron x-ray diffraction study of SrFe₂As₂ at room *T* revealed a *p*-induced second-order transition at 10 GPa from the T to a cT structure for which electronic structure calculations indicated the formation of As–As interlayer bonding as responsible for the lattice collapse.⁵⁶ Another synchrotron x-ray diffraction study at room *T* showed that a cT transition occurs in BaFe₂As₂ at an even higher *p* $\approx$ 27 GPa, much higher than the transition *p* of 1.7 GPa found for the Ca compound at this *T*.⁵⁷ A previous high-*p* synchrotron x-ray diffraction study of the same compound found that the onset *p* of the cT phase at room *T* is 17 GPa under nonhydrostatic conditions and 22 GPa under hydrostatic conditions.⁵⁸ Synchrotron x-ray powder diffraction measurements versus *T* and *p* were also carried out for Ca_{0.67}Sr_{0.33}Fe₂As₂, with results intermediate between those obtained previously for the pure Ca and Sr end-members.⁵⁹ In the Ca(Fe_{1-*x*}Co_{*x*})₂As₂ system, the onset *p* for the cT transition at low *T* for *x* = 0.032, 0.051 and 0.063 decreases with increasing *x*.⁶⁰ At ambient *p*, a *T*-induced transition from the high-*T* T phase to the low-*T* cT phase occurs below $\sim$ 90 K for *x* = 0.05–0.09 in the system CaFe₂(As_{1-*x*}P_{*x*})₂.⁶¹ The doped compounds Ca(Fe_{1-*x*}Rh_{*x*})₂As₂ similarly exhibit an ambient pressure cT phase up to 50 K for *x* = 0.024 and up to 300 K for *x* = 0.19.⁶² The *T*-*p* phase diagrams of lanthanide-doped

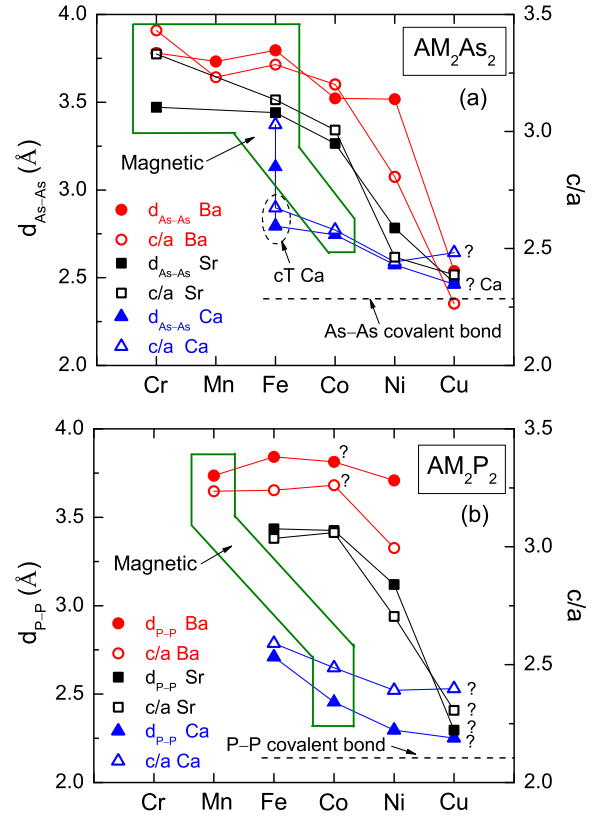


FIG. 21: (Color online) Interlayer As–As distance $d_{\text{As-As}}$ (a) and interlayer P–P distance $d_{\text{P-P}}$ (b) (left ordinates) and *c/a* ratio (right ordinates) versus 3*d* transition metal *M* for AM_2As_2 and AM_2P_2 compounds, respectively. The compounds with magnetically ordered ground states are enclosed in the green boxes. The compounds for which the magnetic ground states are not known are marked with “?”. The references are given in Table VIII.

$\text{Ca}_{1-x}\text{R}_x\text{Fe}_2\text{As}_2$ (*R* = La, Ce, Pr, Nd) compounds, including T and cT phase regions, were also determined.⁶³

In the following Sec. VIII A we examine more quantitatively the systematics of interlayer P–P and As–As bonding in 3*d* transition metal phosphides and arsenides with the ThCr₂Si₂ structure, and we will find that SrCu₂As₂ is in the cT phase. Then in Sec. VIII B we discuss the relationship of the magnetic character of the ThCr₂Si₂-type 3*d* transition metal arsenides and phosphides with the degree of interlayer pnictogen bonding and discuss how the properties of SrCu₂As₂ fit into this scheme. In Sec. VIII C we discuss doping scenarios when Fe is partially substituted by other transition metals, including Cu, in the (Ca, Sr, Ba)Fe₂As₂ compounds.

A. Pnictogen Interlayer Bonding

Several estimates of the (single) covalent bond distances $d_{\text{X-X}}$ have been made for *X* = As and P. In 1988, Von Schnering and Hönle inferred from a study of

TABLE VIII: Magnetic and structural properties of AM_2X_2 compounds ($A = \text{Ca, Sr, Ba}$; $M = \text{Cr, Mn, Fe, Co, Ni, Cu}$; $X = \text{P, As}$) with the ThCr_2Si_2 structure. $d_{X-X} = (1 - 2z_X)c$ and $d_{X-X}^{\text{intra}} = (2z_X - \frac{1}{2})c$ are the interlayer and intralayer distances between the pnictogen atoms, respectively. Separate references are given for the crystal data and magnetic properties. For the latter, the abbreviation AFM means antiferromagnetic and SDW means itinerant spin density wave.

Compound	a (Å)	c (Å)	c/a	z_X	d_{X-X} (Å)	d_{X-X}^{intra} (Å)	Ref.	Magnetic properties
CaFe_2As_2 (T)	3.872(9)	11.730(2)	3.03	0.3665(9)	3.13(2)	2.73(2)	[5]	AFM SDW [5]
CaFe_2As_2 (cT)	3.9792(1)	10.6379(6)	2.67	0.3687(7)	2.79(2)	2.52(2)	[54]	Fe moment quenched [54,55]
CaCo_2As_2	3.9831(2)	10.2732(6)	2.58	0.3664(2)	2.745(4)	2.392(4)	[66]	AFM [66,67]
CaNi_2As_2	4.053(6)	9.90(2)	2.44	0.370	2.574	2.376	[30,33]	Pauli paramagnetic [33]
CaCu_2As_2	4.129(1)	10.251(1)	2.48	0.3799(2)	2.462(4)	2.663(4)	[68]	
SrCr_2As_2	3.918(3)	13.05(1)	3.33	0.367	3.471	3.054	[30,33]	AFM [33]
SrFe_2As_2	3.9289(3)	12.3172(12)	3.13	0.36035(5)	3.440(2)	2.718(2)	[69]	AFM SDW [41]
SrCo_2As_2	3.935(7)	11.83(2)	3.01	0.362	3.265	2.650	[30,33]	Paramagnetic [70]
SrNi_2As_2	4.1374(8)	10.188(4)	2.46	0.3634(1)	2.783(2)	2.311(2)	[71]	No magnetic order [71]
SrCu_2As_2	4.2725(1)	10.2000(3)	2.39	0.3789(1)	2.470(2)	2.630(2)		Nonmagnetic [This work]
BaCr_2As_2	3.963(3)	13.60(1)	3.43	0.361	3.781	3.019	[30,33]	Itinerant AFM [72]
BaMn_2As_2	4.1686(4)	13.473(3)	3.23	0.3615(3)	3.732(8)	3.004(8)	[73]	AFM [73]
BaFe_2As_2	3.9633(4)	13.022(2)	3.29	0.35424(6)	3.797(2)	2.715(2)	[74]	AFM SDW [40]
BaCo_2As_2	3.958(5)	12.67(2)	3.20	0.361	3.522	2.813	[30,33]	Renormalized paramagnet [75]
BaNi_2As_2	4.112(4)	11.54(2)	2.81	0.3476(3)	3.517(7)	2.253(7)	[76]	Pauli paramagnetic [33]
BaCu_2As_2	4.446(5)	10.07(1)	2.26	0.374	2.538	2.497	[30,33]	Pauli paramagnetic [33]
CaFe_2P_2	3.855(1)	9.985(1)	2.59	0.3643(3)	2.710(6)	2.283(6)	[77]	Pauli paramagnetic? [78]
CaCo_2P_2	3.858(1)	9.593(1)	2.49	0.3721(4)	2.454(8)	2.343(8)	[77]	Itinerant AFM [48,49]
CaNi_2P_2	3.916(1)	9.363(1)	2.39	0.3774(5)	2.296(9)	2.386(9)	[77]	Pauli paramagnetic [79]
$\text{CaCu}_{1.75}\text{P}_2$	4.014(1)	9.627(1)	2.40	0.3831(4)	2.251(8)	2.563(8)	[77]	
SrFe_2P_2	3.825(1)	11.612(1)	3.04	0.3521(8)	3.43(2)	2.37(2)	[77]	Pauli paramagnetic [80]
SrCo_2P_2	3.794(1)	11.610(1)	3.06	0.3525(5)	3.42(2)	3.38(2)	[77]	Stoner enhanced paramagnet [81]
SrNi_2P_2	3.948(1)	10.677(3)	2.70	0.3539(3)	3.120(7)	2.219(7)	[82]	Paramagnetic [83]
$\text{SrCu}_{1.75}\text{P}_2$	4.166(1)	9.607(1)	2.31	0.3805(4)	2.296(8)	2.507(8)	[77]	
BaMn_2P_2	4.037(1)	13.061(1)	3.24	0.3570(3)	3.735(8)	2.795(8)	[77]	AFM [84]
BaFe_2P_2	3.840(1)	12.442(1)	3.24	0.3456(4)	3.84(1)	2.38(1)	[77]	Pauli paramagnetic? [78]
BaCo_2P_2	3.7994(3)	12.391(1)	3.26	0.3461(3)	3.814(8)	2.382(8)	[85]	
BaNi_2P_2	3.947(1)	11.820(1)	2.99	0.3431(3)	3.709(7)	2.201(7)	[82]	Pauli paramagnetic [86]

polyphosphides that $d_{\text{P-P}} = 2.23(7)$ Å.⁶⁴ A recent survey in 2008 of the covalent radii of the elements by Cordero et al. gave $d_{\text{P-P}} = 2.14(6)$ Å and $d_{\text{As-As}} = 2.38(8)$ Å.⁶⁵ As will be seen, the difference between the two $d_{\text{P-P}}$ values as well as the error bars on any of these three d_{X-X} values are negligible compared with the variations in the interlayer d_{X-X} values across the various $AM_2(\text{As, P})_2$ series of compounds. Here we will use the $d_{\text{P-P}}$ and $d_{\text{As-As}}$ values of Cordero et al. for consistency.

We have compiled in Table VIII crystallographic data from our work on SrCu_2As_2 together with data from the literature on ThCr_2Si_2 -type AM_2X_2 compounds ($A = \text{Ca, Sr, Ba}$; $M = \text{Cr, Mn, Fe, Co, Ni, Cu}$) with $X = \text{P}$ and As .^{5,33,40,41,54,55,66-86} The d_{X-X} and the c/a ratio for $X = \text{As}$ and P are plotted versus M in Figs. 21(a) and 21(b), respectively. The $d_{\text{P-P}}$ and $d_{\text{As-As}}$ covalent bond distances of Cordero et al.⁶⁵ are plotted as the horizontal dashed lines in the respective figures. The cT phases in each figure are characterized by $d_{\text{As-As}}$ or $d_{\text{P-P}}$ values that approach the respective interlayer covalent bond distance.

From Fig. 21, the d_{X-X} and c/a values for the various ThCr_2Si_2 -type compounds are strongly correlated, as previously documented by Jeitschko et al. for

phosphides.⁵⁰ The $d_{\text{As-As}}$ and $d_{\text{P-P}}$ are plotted versus c/a in Figs. 22(a) and 22(b) for the respective series of AM_2X_2 compounds. An approximate linear relationship is seen between d_{X-X} and c/a for each class of pnictides, with the phosphides following the linear behavior more precisely. Linear least squares fits of the data by

$$d_{X-X} = A + B \frac{c}{a} \quad (30)$$

yield the parameters

$$\begin{aligned} A &= -0.28 \text{ Å}, \quad B = 1.19 \text{ Å}, \quad (X = \text{As}) \\ A &= -1.78 \text{ Å}, \quad B = 1.73 \text{ Å}. \quad (X = \text{P}) \end{aligned} \quad (31)$$

The fits are shown by the green lines in Figs. 22(a) and 22(b), respectively. A plot of $d_{\text{P-P}}$ versus c/a showing an approximate linear relationship for a more diverse range of ThCr_2Si_2 -type phosphides is shown in Fig. 1 of Ref. 50. A plot of $d_{\text{As-As}}$ versus c/a for ambient pressure (Ca, Sr, Ba) Fe_2As_2 and high-pressure cT CaFe_2As_2 showing a linear relationship was given in Fig. S1 of Ref. 87.

For SrCu_2As_2 , our value $d_{\text{As-As}} = 2.470(2)$ Å is close to the As-As covalent bond distance $2.38(8)$ Å, which confirms that the formal oxidation states of Cu and As atoms in this compound are Cu^{+1} and As^{-2} as discussed

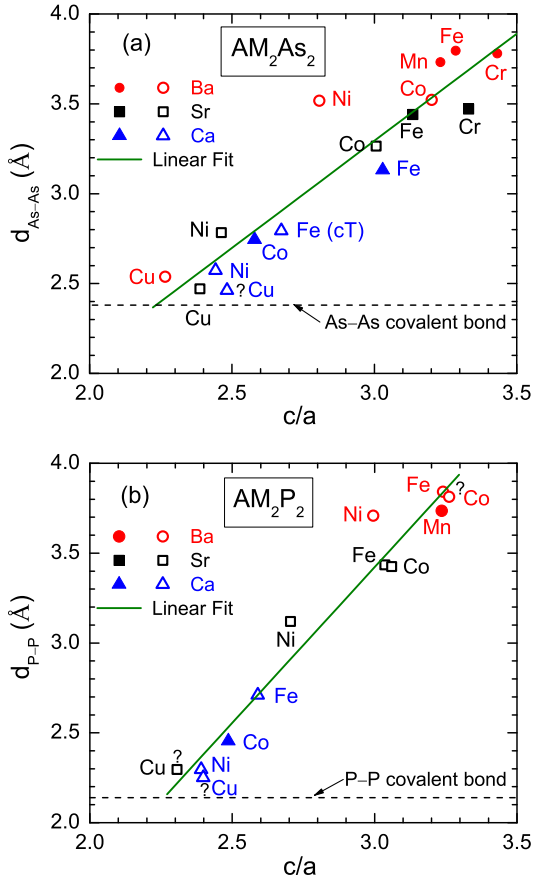


FIG. 22: (Color online) (a) Interlayer As-As distance $d_{\text{As-As}}$ and (b) interlayer P-P distance $d_{\text{P-P}}$ versus c/a in AM_2As_2 and AM_2P_2 compounds, respectively. Linear least-squares fits of the data in (a) and (b) by Eq. (30) are plotted as the respective green lines with parameters given in Eqs. (31). Filled symbols designate magnetically ordered compounds whereas the open symbols refer to compounds that do not have a magnetically ordered ground state. The compounds for which the magnetic ground states are not known are marked with “?”. The references are given in Table VIII.

above. The +1 oxidation state of Cu is consistent with our $\rho(T)$, $C_p(T)$ and $\chi(T)$ measurements of SrCu_2As_2 as also previously discussed. In Sec. IX we suggest that the As-As interlayer covalent bonding in SrCu_2As_2 may be driven by the high stability of the Cu^{+1} d^{10} electronic configuration rather than the Cu^{+1} oxidation state being a result of the As-As interlayer bonding.

B. Correlations between Pnictogen Interlayer Bonding and Magnetic Properties

The $(\text{Ca}, \text{Sr}, \text{Ba})\text{M}_2\text{X}_2$ compounds that exhibit magnetically ordered ground states are indicated in Fig. 21 by a box around them and in Fig. 22 by filled symbols. One sees that with the exception of cT phases CaCo_2P_2 and CaCo_2As_2 which are antiferromagnets,^{48,49,66,67} mag-

netic ordering occurs only for the T phase compounds.

Reehuis et al.⁴⁹ observed for a more extended set of ACo_2P_2 compounds with the ThCr_2Si_2 structure, including A = rare earths, that either long-range magnetic ordering of the Co atoms did not occur or FM ordering occurred if there is little or no P-P interlayer covalent bonding, whereas the character of the magnetic ordering changes to AFM if P-P interlayer bonding occurs (these are cT compounds in our terminology). The latter inference is consistent with our datum for CaCo_2P_2 in Figs. 21 and 22.

Kreyssig, Goldman, Pratt et al. found that whereas CaFe_2As_2 exhibits SDW ordering in the T phase as previously reported,⁵ the pressure-induced transition to the cT phase quenches the magnetic ordering as well as the Fe magnetic moment and associated AFM fluctuations.^{54,55,88} Danura et al. found in the $\text{Ca}(\text{Fe}_{1-x}\text{Rh}_x)_2\text{As}_2$ system that after suppressing the SDW with increasing x , superconductivity appeared at about 13 K at $x \approx 0.02$, but then the superconductivity was quenched at higher x when the compound went into the cT phase.⁶² Furthermore, they found that converting a superconducting T sample with $x \approx 0.02$ to the cT phase under pressure destroyed the superconductivity. The high- p results of Uhoja et al. on BaFe_2As_2 suggested that the p -induced superconductivity with $T_c = 34$ K at $p = 1$ GPa is suppressed in the higher- p stability range of the cT phase.⁵⁸ These results taken together suggest that the superconductivity in these phases is mediated by spin fluctuations.

The degree of $X-X$ covalent bonding and hence the formal oxidation states of the M atoms in the above AM_2As_2 compounds are thus directly correlated with their magnetic and superconducting properties.

From first principles calculations, Yildirim proposed early on that the degree of As-As bonding in CaFe_2As_2 and the magnitude of the Fe spin are inversely related.^{89,90} He suggested that the application of pressure on CaFe_2As_2 causes a reduction in the Fe moment which weakens the Fe-As bonding, and in turn, leads to As-As bonding and hence the cT phase. This prediction of a p -driven transition from a magnetic ground state in the T phase to a nonmagnetic one in the cT phase was confirmed by subsequent first-principles calculations (see, e.g., Ref. 91 in which the effects of nonhydrostatic pressure are also calculated). Yildirim further suggested that the Fe moment should occur at $p = 0$ even in the paramagnetic phase,^{89,90} which was confirmed by the observation of AFM spin fluctuations above the Néel temperature T_N by inelastic neutron scattering measurements on single crystals of the $(\text{Ca}, \text{Sr}, \text{Ba})\text{Fe}_2\text{As}_2$ compounds.^{11,92}

C. Transition Metal M Substitutions in $\text{Ba}(\text{Fe}_{1-x}\text{M}_x)_2\text{As}_2$

Studies of the effects of partially substituting the Fe atoms in the AFe_2As_2 compounds by other transition

metals showed that the long-range SDW ordering and associated lattice distortions in the undoped semimetallic parent compounds had to be largely suppressed before high- T_c superconductivity could occur.¹¹ This was documented, for example, by Canfield and colleagues who determined the T - x phase diagrams of $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ ($M = \text{Co}, \text{Ni}, \text{Cu}, \text{Pd}, \text{Rh}$) from single crystal studies.¹² They showed that the superconducting transition temperature $T_c(x)$, but not the AFM ordering temperature $T_N(x)$, approximately overlapped if the x -axis is replaced by the average d -electron concentration of the transition metal, thus suggesting the importance of this parameter to the superconducting properties.¹² Interestingly, they found that whereas Co and Ni substitutions for Fe induced bulk superconductivity, Cu substitutions did not even though they suppressed the structural and SDW transitions as Co and Ni substitutions do.¹² This has been a conundrum in the FeAs-based superconductivity field. Angle-resolved photoemission spectroscopy (ARPES) measurements on some of these $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ systems support the contention that such aliovalent M -doping increases the electron concentration (see, e.g., the references in Ref. 93).

On the other hand, as discussed above, applying pressure to the parent compounds can cause the same changes without doping. Furthermore, isovalent substitutions of Ru for Fe or P for As in BaFe_2As_2 suppress the SDW and induce high- T_c superconductivity and thus have T - x phase diagrams similar to those of the $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ compounds where M is an aliovalent transition metal.¹¹ Remarkably, Dhaka et al.⁹³ found from angle-resolved photoemission spectroscopy (ARPES) measurements on $\text{Ba}(\text{Fe}_{1-x}\text{Ru}_x)_2\text{As}_2$ crystals that the electronic structure near E_F does not change with Ru doping. They speculated that the suppression of the SDW with Ru substitution and concomitant onset of superconductivity arise from a reduction of the Stoner enhancement factor of the static susceptibility at the ordering wave vector.

Various theoretical studies have been carried out to determine whether the carrier concentration changes upon aliovalent transition metal substitutions for Fe in the AFe_2As_2 compounds. Density functional theory (DFT) calculations by Wadati et al. of the electronic structures of $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ compounds with $M = \text{Co}, \text{Ni}, \text{Cu}, \text{Zn}, \text{Ru}, \text{Rh}$ and Pd suggested that these dopants do not change the carrier concentration because any additional d -electrons are localized on the dopant sites.⁹⁴ On the other hand, another DFT study of disordered substitutions of 12.5% of Co for Fe in BaFe_2As_2 by Berlijn et al.⁹⁵ found that a large chemical potential shift occurs due to the extra d -electron of Co as observed in ARPES experiments,⁹⁶⁻⁹⁸ and that the chemical disorder induces important carrier scattering effects. They also found that the electron concentration due to the doping tends to pile up around the Co dopant sites as found by Wadati et al.,⁹⁴ but that these electrons are associated with band states and are not localized.⁹⁵

On the experimental side, local measurements of the

electronic environments around the Fe and other atoms in $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ have been carried out. Fe K near edge x-ray absorption structure (NEXAS) measurements of the electron density around the iron site in $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ indicate that the extra doped d -electrons are not concentrated at the Fe sites.⁹⁹ Similarly, Merz et al. found from $L_{2,3}$ NEXAS measurements on the Fe, Co and As atoms in the $\text{Sr}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ system that no observable changes in the Fe, Co and As valences occur on Co-doping.¹⁰⁰ Resonant and nonresonant x-ray absorption and emission spectroscopy measurements as well as core and valence level x-ray photoelectron spectroscopy measurements were carried out by McLeod et al.¹⁰¹ on the Fe, Co, Ni and Cu atoms in $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ crystals with $M = \text{Co}, \text{Ni}$ and Cu . They found that there is little charge transfer from the dopant atoms to the Fe atoms and that the iron arsenides are not strongly correlated electron systems. They concluded that the Co and Ni substitutions provide additional conduction electrons, but that the Cu $3d$ electrons are localized in the Cu $3d^{10}$ shell and therefore that Cu-doping reduces the free carrier concentration at the Fermi level.¹⁰¹ Resonant L_3 -edge Fe and Co photoelectron spectroscopy measurements of $\text{Ca}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ crystals with $x = 0.056$ by Levy et al. revealed that the Co $3d$ electrons participate in the formation of the Fermi surface, that the Fe and Co atoms have the same +2 oxidation state, and therefore that the extra d electron of Co is donated to the conduction band but whose charge density is associated mainly with the Co dopant atoms.¹⁰² The totality of all these local measurements on Co and Fe indicate that the doped electrons of Co are itinerant and participate in the formation of the Fermi surface, but that their spatial densities are located near the Co atoms.

Ideta et al. carried out a comprehensive ARPES study of $\text{Ba}(\text{Fe}_{1-x}M_x)_2\text{As}_2$ crystals with $M = \text{Ni}$ ($x = 0.0375, 0.05, 0.08$) and Cu ($x = 0.04, 0.06, 0.08$) including measurements of both the in-plane ab -axis and out-of-plane c -axis Fermi surface dispersions and compared the results with previous ARPES measurements on $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$.¹⁰³ They found that volume enclosed by the electron Fermi surface(s) increased and the volume enclosed by the hole Fermi surface(s) decreased with increasing x for Co, Ni and Cu substitutions for Fe, as expected from electron doping in a rigid band picture. They also found that the d -bands associated with the substituted Co, Ni and Cu atoms have increasing binding energy with respect to E_F , as expected from the increasing impurity potential. However, one also expects in a rigid band approach that the difference $n_e - n_h$ between the numbers of electron and hole carriers per doped Co, Ni or Cu atom should be equal to the number of extra donated d -electrons per atom. From the difference between the volumes enclosed by the electron and hole Fermi surfaces, they found this prediction to be violated for Ni and Cu dopants, with the itinerant electrons doped per atom by Ni and especially by Cu smaller than the expected

values of two and three, respectively.¹⁰³ They suggested that $n_e - n_h$ is too small for Ni and Cu substitutions either because some of the donated electrons occupy impurity bands that do not cross the Fermi level or they occupy localized states. When the authors plotted the SDW Néel temperature T_N and the superconducting T_c versus $n_e - n_h$, they found universal behaviors for both quantities for all three dopants Co, Ni and Cu. Thus although the rigid band picture is not accurate with respect to electron doping, Ideta et al. have identified a quantity that controls both T_N and T_c in electron-doped BaFe_2As_2 .¹⁰³

The Divergent Properties of SrCu_2As_2 and Cu-doped BaFe_2As_2 and the Role of As-As Interlayer Bonding

In this paper, we have conclusively demonstrated from physical property measurements that SrCu_2As_2 is an sp -band metal. We have also demonstrated that As-As interlayer covalent bonding occurs in this compound, which is consistent with the Cu^{+1} oxidation and with the non-magnetic d^{10} electronic configuration. In a band picture, the Cu 3d-bands at ~ 3 eV binding energy below E_F are fully occupied and the Cu d -orbitals contribute little to the bands at E_F .²⁹ Therefore, on the basis of our results, the most natural and straightforward expectation for the effect of partially substituting Cu for Fe in the $(\text{Ca}, \text{Sr}, \text{Ba})\text{Fe}_2\text{As}_2$ compounds is that such Cu substitutions result in strong hole-doping instead of the expected²⁶ strong electron doping. In this case, the hole-doping resulting from replacing Cu for Fe in the AFe_2As_2 compounds would be qualitatively similar to hole-doping resulting from partial substitutions of Mn or Cr for Fe. This analogous doping behavior would empirically explain why strongly suppressed and non-bulk superconductivity with $T_c \lesssim 2$ K was observed in Cu-substituted BaFe_2As_2 ,²⁶ since partially substituting Mn or Cr for Fe does not induce superconductivity.^{21–25} The origin of the latter behavior, however, is not understood microscopically at present, especially since hole-doping by partially substituting K for Ba in BaFe_2As_2 induces superconductivity with T_c up to 38 K.¹

However, as discussed above, it has been demonstrated both experimentally and theoretically that low-level substitutions of Cu for Fe in BaFe_2As_2 result in electron doping rather than hole doping. Furthermore, from Figs. 21 and 22, interlayer As-As bonding does not occur in BaFe_2As_2 whereas it does in BaCu_2As_2 . These differences indicate that the As-As bonding character and associated Cu doping character in $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ must change with increasing x , as possibly suggested from thermoelectric power and Hall effect measurements on single crystals of this system.¹⁰⁵ At small x , the Cu evidently replaces the $3d^6$ Fe^{+2} atoms as a $3d^9$ Cu^{+2} electron dopant, but at high concentrations would dope as $3d^{10}$ Cu^{+1} , which would correspond to a crossover between electron and hole doping with increasing x . However, to

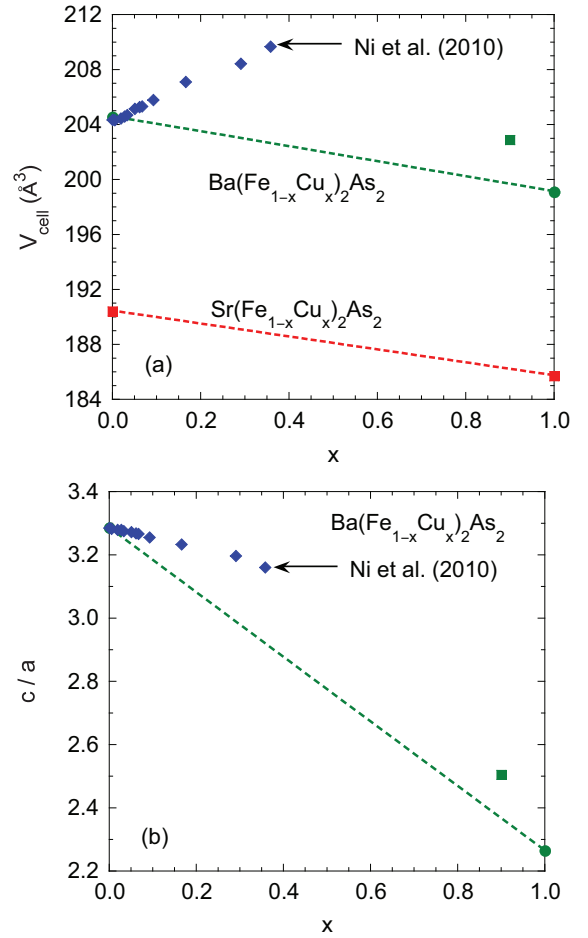


FIG. 23: (Color online) (a) Unit cell volume V_{cell} versus composition x in $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ (upper sets of data) and for the two endpoints $x = 0$ and $x = 1$ of $\text{Sr}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$. The $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ data with blue diamond symbols are from Ni et al.²⁶ and the green square at $x = 0.9$ is a preliminary result of the present authors. The remaining data are from the literature.¹¹ All compounds have the bct ThCr_2Si_2 -type structure. The two dashed lines represent Vegard's law for the respective series of compounds. (b) The c/a ratio versus x for the $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ system. The data symbols have the same meaning as in (a).

accommodate the change in the interlayer As-As bonding from nonbonding to full covalent bonding and considering the very dissimilar chemistry expected for Cu^{+1} and Fe^{+2} with increasing x , phase-separation (a miscibility gap) might occur in the $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ system, as we have demonstrated to occur in the $\text{Ba}(\text{Fe}_{1-x}\text{Mn}_x)_2\text{As}_2$ system.¹⁰⁴ Our preliminary studies of powder samples of $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ indeed suggest the presence of a miscibility gap in this system for $0.7 \lesssim x \lesssim 0.9$.⁶⁶

Detailed structure refinements versus x of $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ would shed light on the nature of the As-As bonding and the doping character of Cu, but such structure refinements have not been reported up to now. However, Ni et al.²⁶ reported the lattice

parameters a and c and the unit cell volume $V_{\text{cell}} = a^2c$ of $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ versus x up to $x = 0.35$; their results for V_{cell} versus x are shown in Fig. 23(a). Also included is our preliminary datum for a polycrystalline sample with $x = 0.9$ that was quenched from 900°C , together with literature data for BaFe_2As_2 , BaCu_2As_2 , SrFe_2As_2 and SrCu_2As_2 .¹¹ These four compounds have the same tetragonal ThCr_2Si_2 -type structure. Between the $x = 0$ and $x = 1$ end points of the Ba and Sr series, one sees from Fig. 23(a) that the volume decreases in each series by about the same amount of $\approx 5 \text{ \AA}^3$. However, the data of Ni et al.²⁶ for $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ show a qualitative deviation from Vegard's law, exhibiting a strong increase in V_{cell} with increasing x instead of the expected decrease. This anomalous behavior may indicate interesting changes in the As–As bonding, Cu oxidation state and doping behavior versus x . In view of Fig. 22(b), we have plotted c/a versus x for the $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ system in Fig. 23(b). The trend of the data suggest that interlayer As–As bonds may be beginning to form by $x \sim 0.35$. Detailed structural studies are clearly called for to clarify these characteristics versus Cu substitution concentration in FeAs-based ThCr_2Si_2 -type systems.

IX. SUMMARY AND CONCLUSIONS

We have presented experimental data on the crystallographic properties in Sec. III and physical properties in Secs. IV–VII of single crystals of SrCu_2As_2 , SrCu_2Sb_2 and BaCu_2Sb_2 and of aligned clusters of $\text{SrCu}_2(\text{As}_{0.84}\text{Sb}_{0.16})_2$ crystals that were synthesized by the self-flux growth method. Contrasting structures were observed for SrCu_2As_2 (ThCr_2Si_2 -type), SrCu_2Sb_2 (CaBe_2Ge_2 -type) and BaCu_2Sb_2 (a coherent intergrowth of ThCr_2Si_2 -type and CaBe_2Ge_2 -type unit cells, likely with a monoclinic distortion). The $C_p(T)$ and $\rho(T)$ measurements show metallic behaviors for all four compounds. The $\chi(T)$ data exhibit nearly T -independent diamagnetic behaviors. The χ of SrCu_2As_2 is found to be larger in the ab -plane than along the c -axis, whereas the χ values of SrCu_2Sb_2 and BaCu_2Sb_2 are larger along the c -axis. These differences in anisotropy appear to arise from the differences in the crystal structures between these compounds. No evidence was observed from any of our measurements between 1.8 and 350 K for any phase transitions in any of the four compounds.

In Secs. IV–VII, we estimated the different contributions to the intrinsic χ and analyzed the $C_p(T)$ and $\rho(T)$ data within the frameworks of the Debye model of lattice heat capacity and the Bloch–Grüneisen model of resistivity, respectively. The T -dependence of ρ is explained by electron-phonon scattering, as expected for an sp -band metal. In particular, there is no clear evidence for a T^2 temperature dependence that would have indicated a significant contribution of d orbitals to the density of states at the Fermi energy E_F . Furthermore, our data rule out

the possibility that the Cu ions are present as Cu^{+2} local magnetic moments with a $3d^9$ electronic configuration and spin $S = 1/2$.

Thus we conclude from the electronic and magnetic properties of these four compounds that they are all nonmagnetic sp -metals, as previously predicted by D. J. Singh from electronic structure calculations for SrCu_2As_2 and BaCu_2As_2 with the ThCr_2Si_2 -type structure.²⁹ These predictions are that the $3d$ bands of Cu are narrow and are centered about 3 eV below E_F , so they are completely filled, and there is little admixture of the $3d$ states into those at E_F . In chemical language this corresponds to a formal oxidation state of Cu^{+1} with a nonmagnetic $3d^{10}$ electronic configuration. As discussed in Sec. VIII A, for SrCu_2As_2 the Cu^{+1} oxidation state is consistent with the presence of the observed interlayer covalent As–As bonding, which together with the expected oxidation state Sr^{+2} yields $\text{As}^{-2} \equiv [\text{As} - \text{As}]^{-4}/2$.

On the other hand, for SrCu_2Sb_2 with the CaBe_2Ge_2 -type structure, no Sb–Sb interlayer bonding is possible [see Fig. 4(b)] and the compound still shows the same physical properties as SrCu_2As_2 , again indicating a Cu^{+1} formal oxidation state and $3d^{10}$ electronic configuration. It appears that the concept of formal oxidation state loses its meaning for Sb in SrCu_2Sb_2 because one cannot derive the Cu^{+1} oxidation state from an assumed oxidation state Sb^{-2} associated with the presence of Sb–Sb bonding. In both SrCu_2As_2 and SrCu_2Sb_2 , the nonmagnetic character of Cu and the d^{10} electronic configuration evidently arise because of the stability of this electronic configuration. In a band picture, the large Cu impurity potential causes the Cu $3d$ bands to be far below E_F , inhibiting their participation in the electronic conduction. The above dichotomy between the As and Sb compounds in fact suggests that the As–As covalent bonding observed in SrCu_2As_2 is driven by the stability of the Cu^{+1} oxidation state. A band structure calculation for SrCu_2Sb_2 and a comparison with that of SrCu_2As_2 , together with measurements of the local electronic configurations of Sr, Cu and Sb in both SrCu_2As_2 and SrCu_2Sb_2 , would help to clarify these issues.

As discussed in Sec. VIII C, a topic that is currently being strongly debated is by how much, and even whether, transition metal substitutions on the Fe sites in AFe_2As_2 compounds change the conduction carrier concentration. Early in the development of the iron arsenide high- T_c field, it appeared that substituting Co, Ni and Cu for Fe donates an additional one, two or three electrons to the conduction bands of the system, respectively,¹² but that expectation has been contested on several fronts. Our results on SrCu_2As_2 show that this compound is a collapsed tetragonal phase with Cu in the Cu^{+1} oxidation state with a d^{10} electronic configuration. This electron configuration suggests that substituting Cu for Fe in $(\text{Ca}, \text{Sr}, \text{Ba})(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ should result in hole-doping rather than the observed electron doping. Thus the electronic character of the Cu dopant and the strength of the As–As interlayer bonding are

both expected to drastically change between weakly Cu-substituted BaFe_2As_2 and pure BaCu_2As_2 , perhaps via a first-order lattice instability such as a miscibility gap in the $\text{Ba}(\text{Fe}_{2-x}\text{Cu}_x)_2\text{As}_2$ system. Detailed studies of the crystallography of $(\text{Ca},\text{Sr},\text{Ba})(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ versus x would help to clarify the changes in the As-As interlayer bonding and the nature of the carrier doping by Cu with increasing x .

Acknowledgments

We thank Paul Canfield, Rajendra Dhaka and David Singh for helpful comments. This research was supported

by the U.S. Department of Energy, Office of Basic Energy Sciences, Division of Materials Sciences and Engineering. Ames Laboratory is operated for the U.S. Department of Energy by Iowa State University under Contract No. DE-AC02-07CH11358.

* Electronic address: vanand@ameslab.gov

† Electronic address: johnston@ameslab.gov

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